

# LM63635C-Q1 3.5V to 36V, 3.25A, Automotive Step-Down Voltage Converter

## 1 Features

- AEC-Q100-Qualified for automotive applications
  - Device temperature grade 1:  $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$  ambient operating temperature
- **Functional Safety-Capable**
  - [Documentation available to aid functional safety system design](#)
- Supports automotive system requirements
  - Input voltage range: 3.5V to 36V
  - Short minimum on-time of 50ns
  - Good EMI performance
  - Psuedo-random spread spectrum
  - Compatible with CISPR 25
  - Low operating quiescent current of 23 $\mu\text{A}$
  - Junction temperature range  $-40^{\circ}\text{C}$  to  $+150^{\circ}\text{C}$
- High design flexibility with minimal external components
  - Fixed  $V_{\text{OUT}}$  at 3.3V or 5V
  - Fixed switching frequency at 400kHz or 2.1MHz
  - Output current up to 3.25A
- Small design size
  - As small as: 14mm  $\times$  14mm for 3.25A, 2.2MHz with WSON package
  - Highly integrated design with low external component count

## 2 Applications

- [Automotive infotainment and cluster](#)
- [Automotive body electronics and lighting](#)
- [Automotive ADAS](#)

## 3 Description

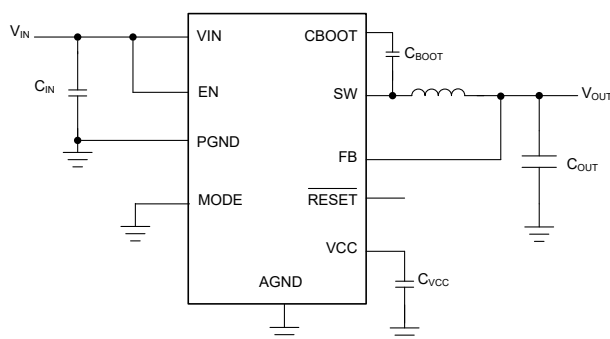
The LM63635C-Q1 regulator is an easy-to-use, synchronous, step-down, DC/DC converter designed for rugged automotive applications. The LM63635C-Q1 can drive up to 3.25A of load current from an input of up to 36V. The converter has high light load efficiency and output accuracy in a small design size. Features such as a  $\overline{\text{RESET}}$  flag and precision enable provide both flexible and easy-to-use solutions for a wide range of applications. Automatic frequency foldback at light load improves efficiency while maintaining tight load regulation. Integration eliminates many external components and provides a pinout designed for simple PCB layout. Protection features include thermal shutdown, input undervoltage lockout, cycle-by-cycle current limit, and hiccup short-circuit protection. The LM63635C-Q1 is available in a WSON 12-pin power package.

### Package Information

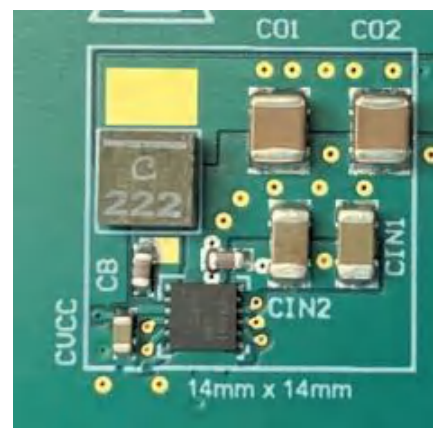
PART NUMBER	PACKAGE <sup>(1)</sup>	PACKAGE SIZE <sup>(2)</sup>
LM63635C-Q1	DRR (WSON, 12)	3.00mm $\times$ 3.00mm

(1) For more information, see [Section 11](#).

(2) The package size (length  $\times$  width) is a nominal value and includes pins, where applicable.



**Simplified Schematic**



**Typical Design Example  $I_{\text{OUT}} = 3.25\text{A}$ ,  $f_{\text{sw}} = 2200\text{kHz}$**



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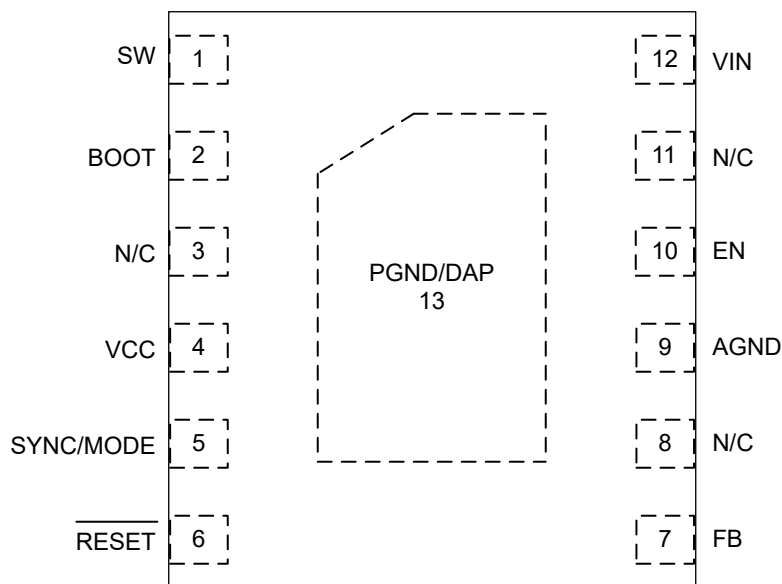
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## 4 Device Comparison Table

ORDER NUMBER <sup>(1)</sup>	PACKAGE	RATED CURRENT	F <sub>SW</sub>	VOUT	PACKAGE SIZE
LM63635CC3QDRRRQ1	DRR0012 (WSON)	3.25A	Fixed 2.1MHz	Fixed 3.3V	3.00mm × 3.00mm
LM63635CC5QDRRRQ1				Fixed 5V	
LM63635CA3QDRRRQ1			Fixed 400kHz	Fixed 3.3V	
LM63635CA5QDRRRQ1				Fixed 5V	

(1) For more information on device orderable part numbers, see [Device Nomenclature](#).

## 5 Pin Configuration and Functions



**Figure 5-1. DRR Package, 12-Pin WSON With PowerPAD™ Integrated Circuit Package — LM63635C-Q1 (Top View)**

**Table 5-1. Pin Functions**

PIN			DESCRIPTION
NAME	WSON LM63635C	TYPE	
SW	1	P	Regulator switch node. Connect to power inductor.
CBOOT	2	P	Bootstrap supply voltage for internal high-side driver. Connect a high-quality, 220nF capacitor from this pin to the SW pin.
NC	3	—	No internal connection to device
VCC	4	A	Internal 5V LDO output. Used as supply to internal control circuits. Do not connect to external loads. Can be used as logic supply for regulator functions. Connect a high-quality, 1µF capacitor from this pin to PGND.
SYNC/MODE	5	A	Mode selection and synchronization input. Tie to VCC for Forced PWM (FPWM) mode, AGND for AUTO mode, or supply an external synchronizing clock to this input.
RESET	6	A	Open-drain power-good flag output. Connect to a suitable voltage supply through a current limiting resistor. High = power OK, low = power bad. Flag pulls low when EN = Low. Can be open when not used.
FB	7	A	Feedback input to regulator. Connect to output capacitor. Do not float; do not ground.
NC	8	—	No internal connection to device
AGND	9	G	Analog ground for regulator and system. Ground reference for internal references and logic. All electrical parameters are measured with respect to this pin. Connect to system ground on PCB.
EN	10	A	Enable input to regulator. High = ON, Low = OFF. Can be connected directly to VIN. Do not float.
NC	11	—	No internal connection to device
VIN	12	P	Input supply to regulator. Connect a high-quality bypass capacitor or capacitors directly to this pin and PGND.
PGND	13	G	Power ground terminal. Connect to system ground and AGND. Connect to bypass capacitor with short wide traces.
DAP	13	G	Electrical ground and heat sink connection. Solder directly to system ground plane.
A = Analog, P = Power, G = Ground			

## 6 Specifications

### 6.1 Absolute Maximum Ratings

Over the recommended junction temperature range <sup>(1)</sup>

PARAMETER		MIN	MAX	UNIT
	VIN to PGND	−0.3	42	V
	EN to AGND	−0.3	42	V
	RESET to AGND	−0.3	16	V
	FB to AGND (Fixed VOUT mode)	−0.3	16	V
	AGND to PGND	−0.3	0.3	V
	SW to PGND for transients of less than 10ns	−6	42	V
	BOOT to SW	−0.3	5.5	V
	VCC to AGND	−0.3	5.5	V
T <sub>J</sub>	Junction temperature	−40	150	°C
T <sub>stg</sub>	Storage temperature	−65	150	°C

- (1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

### 6.2 ESD Ratings

			VALUE	UNIT
V <sub>(ESD)</sub>	Electrostatic discharge	Human-body model (HBM), per AEC Q100-002 <sup>(1)</sup>	±2000	V
		Charged-device model (CDM), per AEC Q100-011	±750	V

- (1) AEC Q100-002 indicates that HBM stressing must be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

### 6.3 Recommended Operating Conditions

Over the recommended junction temperature range of −40°C to 150°C (unless otherwise noted) <sup>(1)</sup>

		MIN	MAX	UNIT
	VIN to PGND	3.5	36	V
	EN	0	36	V
	RESET	0	5	V
	V <sub>CC</sub>	2.7	5.25	V
	I <sub>OUT</sub>	0	3.25	A

- (1) Recommended operating conditions indicate conditions for which the device is intended to be functional. For specified specifications, see the *Electrical Characteristics* table.

### 6.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>		LM63635C-Q1	UNIT
		DRR0012 (WSON)	
		12 PINS	
R <sub>θJA</sub>	Junction-to-ambient thermal resistance <sup>(2)</sup>	47.4	°C/W
R <sub>θJC(top)</sub>	Junction-to-case (top) thermal resistance	44.6	°C/W
R <sub>θJB</sub>	Junction-to-board thermal resistance	20.7	°C/W
Ψ <sub>JT</sub>	Junction-to-top characterization parameter	0.7	°C/W
Ψ <sub>JB</sub>	Junction-to-board characterization parameter	20.7	°C/W

## 6.4 Thermal Information (continued)

THERMAL METRIC <sup>(1)</sup>		LM63635C-Q1	UNIT
		DRR0012 (WSON)	
		12 PINS	
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	6.3	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application note.
- (2) The value of  $R_{\theta JA}$  given in this table is only valid for comparison with other packages and can not be used for design purposes. These values were calculated in accordance with JESD 51-7, and simulated on a 4-layer JEDEC board. The values do not represent the performance obtained in an actual application. For design information please see the *Maximum Ambient Temperature* section.

## 6.5 Electrical Characteristics

Limits apply over the junction temperature ( $T_J$ ) range of  $-40^{\circ}\text{C}$  to  $+150^{\circ}\text{C}$ , unless otherwise stated. Minimum and maximum limits are specified through test, design or statistical correlation. Typical values represent the most likely parametric norm at  $T_J = 25^{\circ}\text{C}$ , and are provided for reference purposes only. Unless otherwise stated, the following conditions apply:  $V_{IN} = 13.5\text{V}$ . <sup>(1)</sup>

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>SUPPLY VOLTAGE (VIN PIN)</b>						
$V_{IN}$	Minimum operating input voltage				3.5	V
$I_Q$	Non-switching input current; measured at VIN pin <sup>(2)</sup>	$V_{EN} = 3.3\text{V}$ , $V_{FB} = 1.2\times$ regulation point		23	40	$\mu\text{A}$
$I_{SD}$	Shutdown quiescent current; measured at VIN pin	$V_{EN} = 0\text{V}$		5.3	10	$\mu\text{A}$
$V_{UVLO\_R}$	Minimum operating voltage threshold	Rising $V_{IN}$ , $I_{VCC} = 0\text{A}$			3.5	V
$V_{UVLO\_F}$	Minimum operating voltage threshold	Falling $V_{IN}$ , $I_{VCC} = 0\text{A}$	2.6		3	V
$I_{POR}$	Pulldown current on SW when OVP is triggered	$V_{EN} = 0\text{V}$ , $V_{SW} = 5\text{V}$	0.5	1.5	2.5	mA
<b>ENABLE (EN PIN)</b>						
$V_{EN-VCC}$	VCC enable voltage	$V_{EN}$ rising		0.85		V
$V_{EN-H}$	Precision enable high level for VOUT	$V_{EN}$ rising	1.425	1.5	1.575	V
$V_{EN-L}$	Precision enable low level for VOUT	$V_{EN}$ falling	0.9	0.94		V
$I_{LKG-EN}$	Enable input leakage current	$V_{EN} = 13.5\text{V}$	-100	0.2	300	nA
<b>INTERNAL LDO</b>						
$V_{CC}$	Internal VCC voltage	$6\text{V} \leq V_{IN} \leq$ maximum operating $V_{IN}$	4.75	5	5.25	V
$V_{CCM}$	VCC clamp voltage	1mA sourced into VCC	5.25	5.55	5.8	V
<b>VOLTAGE REFERENCE (FB PIN)</b>						
$V_{FB\_5V}$	Feedback voltage	$V_{IN} = 5.5\text{V}$ - maximum operating $V_{IN}$	4.925	5	5.075	V
$V_{FB\_3p3V}$	Feedback voltage	$V_{IN} = 3.8\text{V}$ - maximum operating $V_{IN}$	3.25	3.3	3.35	V
$I_{FB\_5V}$	Input leakage current at FB PIN	FB = 5V		2.89	3.4	$\mu\text{A}$
$I_{FB\_3p3V}$	Input leakage current at FB PIN	FB = 3.3V		1.67	2	$\mu\text{A}$
<b>CURRENT LIMITS</b>						
$I_{SC}$	Short-circuit high side current Limit		3.9	4.4	5.4	A
$I_{LS-LIMIT}$	Low side current limit		3.2	3.7	4.4	A
$I_{PEAK-MIN}$	Minimum peak inductor current			0.62	1.25	A
$I_{L-NEG}$	Negative current limit		-1.49	-1.2	-0.75	A
$V_{HICCUP}$	Hiccup threshold on FB pin		37	42	47	%
<b>POWER GOOD (RESET PIN)</b>						
$V_{RESET-HIGH}$	RESET upper threshold - rising	% of FB voltage	110	112	115	%
$V_{RESET-LOW}$	RESET lower threshold - falling	% of FB voltage	91	93	95	%
$V_{RESET-HYS}$	RESET hysteresis	% of FB voltage,	1.1	1.8	2.5	%
$V_{RESET\_VALID}$	Minimum input voltage for proper PG function	Measured when $V_{RESET} < 0.4\text{V}$ with 10k $\Omega$ pullup to external 5V	0.7	1.04	1.25	V
$R_{RESET}$	RESET ON resistance	$V_{EN} = 5\text{V}$ , 1mA pullup current		60	150	$\Omega$
$R_{RESET}$	RESET ON resistance	$V_{EN} = 0\text{V}$ , 1mA pullup current		40	125	$\Omega$
<b>OSCILLATOR (SYNC/MODE PIN)</b>						
$V_{SYNC-HIGH}$	Sync input and mode high level threshold			1.5	1.8	V

## 6.5 Electrical Characteristics (continued)

Limits apply over the junction temperature ( $T_J$ ) range of  $-40^{\circ}\text{C}$  to  $+150^{\circ}\text{C}$ , unless otherwise stated. Minimum and maximum limits are specified through test, design or statistical correlation. Typical values represent the most likely parametric norm at  $T_J = 25^{\circ}\text{C}$ , and are provided for reference purposes only. Unless otherwise stated, the following conditions apply:  $V_{IN} = 13.5\text{V}$ . <sup>(1)</sup>

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{\text{SYNC-HYS}}$	Sync input hysteresis			0.355		V
$V_{\text{SYNC-LOW}}$	Sync input and mode low level threshold		0.8	1.15		V
$R_{\text{SYNC}}$	Pulldown on MODE pin			100		k $\Omega$
<b>MOSFETS</b>						
$R_{\text{DS-ON-HS}}$	High-side MOSFET on-resistance	Load = 1A		93		m $\Omega$
$R_{\text{DS-ON-LS}}$	Low-side MOSFET on-resistance	Load = 1A		61		m $\Omega$
$V_{\text{CBOOT-UVLO}}$	$C_{\text{BOOT}}$ - SW UVLO threshold <sup>(3)</sup>			2.13		V

- (1) MIN and MAX limits are 100% production tested at  $25^{\circ}\text{C}$ . Limits over the operating temperature range verified through correlation using Statistical Quality Control (SQC) methods. Limits are used to calculate Average Outgoing Quality Level (AOQL).
- (2) Non-switching quiescent input current is the current used by the device in open loop. The specified value does not represent the total input current of the system when in regulation.
- (3) When the  $C_{\text{BOOT}}$  capacitor voltage falls below  $V_{\text{CBOOT-UVLO}}$ , the low side MOSFET is turned on to recharge the boot capacitor



## 6.6 Timing Requirements

Limits apply over the junction temperature ( $T_J$ ) range of  $-40^{\circ}\text{C}$  to  $+150^{\circ}\text{C}$ , unless otherwise stated. Minimum and maximum limits are specified through test, design or statistical correlation. Typical values represent the most likely parametric norm at  $T_J = 25^{\circ}\text{C}$ , and are provided for reference purposes only. Unless otherwise stated, the following conditions apply:  $V_{IN} = 13.5\text{V}$ . <sup>(1)</sup>

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>CURRENT LIMITS AND HICCUP</b>						
$N_{OC}$	Number of switching current limit continuous events before hiccup is tripped			128		Cycles
$t_{OC}$	Overcurrent hiccup retry delay time		70	104	140	ms
$t_{OC\_active}$	Time after soft start done timer before hiccup current protection is enabled		11	16	22	ms
<b>SOFT START</b>						
$t_{SS}$	Internal soft-start time		1	1.6	2.2	ms
$t_{SS\_DONE}$	Soft-start done timer		5	8	11	ms
<b>POWER GOOD (<math>\overline{\text{RESET}}</math> PIN) and OVERVOLTAGE PROTECTION</b>						
$t_{dg}$	$\overline{\text{RESET}}$ edge deglitch delay		10	17	30	$\mu\text{s}$
$t_{RISE-DELAY}$	$\overline{\text{RESET}}$ active time	Time FB must be valid before $\overline{\text{RESET}}$ is released.	2	3	5	ms
<b>OSCILLATOR (SYNC/MODE PIN)</b>						
$t_{ON\_OFF-SYNC}$	Sync input ON and OFF time		100			ns
$t_{ON\_OFF-SYNC}$	Sync input ON-time 250KHz		100			ns
$t_{ON\_OFF-SYNC}$	Sync input OFF-time 250KHz		100			ns
$t_{ON\_OFF-SYNC}$	Sync input ON-time 2.2MHz		100			ns
$t_{ON\_OFF-SYNC}$	Sync input OFF-time 2.2MHz		100			ns

(1) MIN and MAX limits are 100% production tested at  $25^{\circ}\text{C}$ . Limits over the operating temperature range are verified through correlation using Statistical Quality Control (SQC) methods. Limits are used to calculate Average Outgoing Quality Level (AOQL).

## 6.7 Switching Characteristics

Limits apply over the junction temperature ( $T_J$ ) range of  $-40^{\circ}\text{C}$  to  $+150^{\circ}\text{C}$ , unless otherwise stated. Minimum and maximum limits are specified through test, design or statistical correlation. Typical values represent the most likely parametric norm at  $T_J = 25^{\circ}\text{C}$ , and are provided for reference purposes only. Unless otherwise stated, the following s apply:  $V_{IN} = 13.5\text{V}$ . <sup>(1)</sup>

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>PWM LIMITS (SW PINS)</b>						
$t_{ON-MIN}$	Minimum switch on-time	$V_{IN} = 12\text{V}$ , $I_{SW} = 1\text{A}$		50	75	ns
$t_{OFF-MIN}$	Minimum switch off-time	$V_{IN} = 5\text{V}$		50	100	ns
$t_{ON-MAX}$	Maximum switch on-time	HS timeout in dropout	5.4	7	10	$\mu\text{s}$
<b>OSCILLATOR</b>						
$f_{OSC}$	Internal oscillator frequency	2.1MHz Fsw version	1.85	2.1	2.35	MHz
$f_{OSC}$	Internal oscillator frequency	400kHz Fsw version	360	400	440	kHz
<b>SPREAD SPECTRUM</b>						
$f_{PSS(2)}$	Spread spectrum pseudo random pattern frequency	$f_{OSC} = 2.1\text{MHz}$		0.98		Hz
$f_{SPREAD}$	Spread of internal oscillator with spread spectrum enabled		-5		5	

- (1) MIN and MAX limits are 100% production tested at  $25^{\circ}\text{C}$ . Limits over the operating temperature range are verified through correlation using Statistical Quality Control (SQC) methods. Limits are used to calculate Average Outgoing Quality Level (AOQL).

## 6.8 System Characteristics

The following specifications apply only to the typical applications circuit with nominal component values. Specifications in the typical (TYP) column apply to  $T_J = 25^\circ\text{C}$  only. Specifications in the minimum (MIN) and maximum (MAX) columns apply to the case of typical components over the temperature range of  $T_J = -40^\circ\text{C}$  to  $150^\circ\text{C}$ . These specifications are not ensured by production testing.

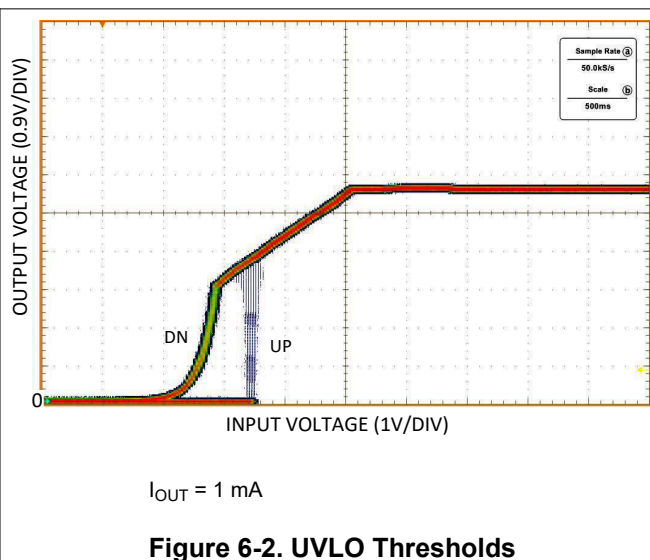
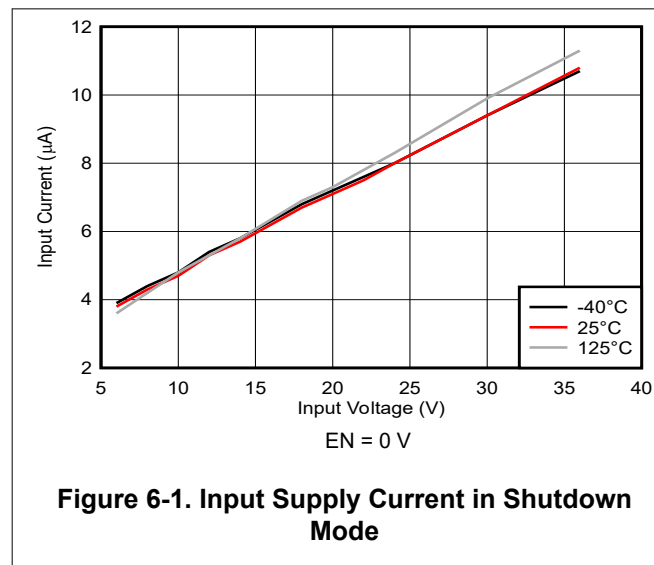
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>SUPPLY VOLTAGE (VIN PIN)</b>						
$I_{\text{SUPPLY}}$	Input supply current when in regulation	$V_{\text{IN}} = 12\text{V}$ , $V_{\text{OUT}} = 3.3\text{V}$ , $I_{\text{OUT}} = 0\text{A}$ , $R_{\text{FBT}} = 1\text{M}\Omega$		23		$\mu\text{A}$
$V_{\text{DROP}}$	Dropout voltage; ( $V_{\text{IN}} - V_{\text{OUT}}$ )	$V_{\text{OUT}} = 5\text{V}$ , $I_{\text{OUT}} = 1\text{A}$ , $F_{\text{SW}} = 1850\text{kHz}$		0.95		V
$V_{\text{DROP}}$	Dropout voltage; ( $V_{\text{IN}} - V_{\text{OUT}}$ )	$V_{\text{OUT}} = 5\text{V}$ , $I_{\text{OUT}} = 1\text{A}$ , $V_{\text{OUT}} - 1\%$ of regulation, $F_{\text{SW}} = 140\text{kHz}$		150		mV
$D_{\text{MAX}}$	Maximum switch duty cycle <sup>(2)</sup>	$V_{\text{IN}} = V_{\text{OUT}} = 12\text{V}$ , $I_{\text{OUT}} = 1\text{A}$		98		%
<b>VOLTAGE REFERENCE (FB PIN)</b>						
$V_{\text{OUT}}^{(1)}$	$V_{\text{OUT}} = 5\text{V}$	$V_{\text{IN}} = 7\text{V}$ to $30\text{V}$ , $I_{\text{OUT}} = 1\text{A}$ to full load, CCM	-1.5		1.5	%
		$V_{\text{IN}} = 7\text{V}$ to $30\text{V}$ , $I_{\text{OUT}} = 0\text{A}$ to full load, AUTO mode	-1.5		2.5	%
	$V_{\text{OUT}} = 3.3\text{V}$	$V_{\text{IN}} = 3.8\text{V}$ to $30\text{V}$ , $I_{\text{OUT}} = 1\text{A}$ to full load, CCM	-1.5		1.5	%
		$V_{\text{IN}} = 3.8\text{V}$ to $30\text{V}$ , $I_{\text{OUT}} = 0\text{A}$ to full load, AUTO mode	-1.5		2.5	%
$t_{\text{SYNC-L}}$	Delay from sync clock staying low to PFM entry			100		ns
$t_{\text{SYNC-H}}$	Delay from sync clock staying high to default frequency			100		ns
<b>THERMAL SHUTDOWN</b>						
$T_{\text{SD}}$	Thermal shutdown temperature	Shutdown temperature	155	163	175	$^\circ\text{C}$
$T_{\text{SDR}}$	Thermal shutdown temperature	Recovery temperature		150		$^\circ\text{C}$

(1) Deviation is with respect to  $V_{\text{IN}} = 13.5\text{V}$ ,  $I_{\text{OUT}} = 1\text{A}$ .

(2) In dropout the switching frequency drops to increase the effective duty cycle. The lowest frequency is clamped at approximately:  $f_{\text{MIN}} = 1 / (t_{\text{ON-MAX}} + t_{\text{OFF-MIN}})$ .  $D_{\text{MAX}} = t_{\text{ON-MAX}} / (t_{\text{ON-MAX}} + t_{\text{OFF-MIN}})$ .

## 6.9 Typical Characteristics

Unless otherwise specified the following conditions apply:  $T_A = 25^\circ\text{C}$ ,  $V_{IN} = 13.5\text{ V}$



## 7 Detailed Description

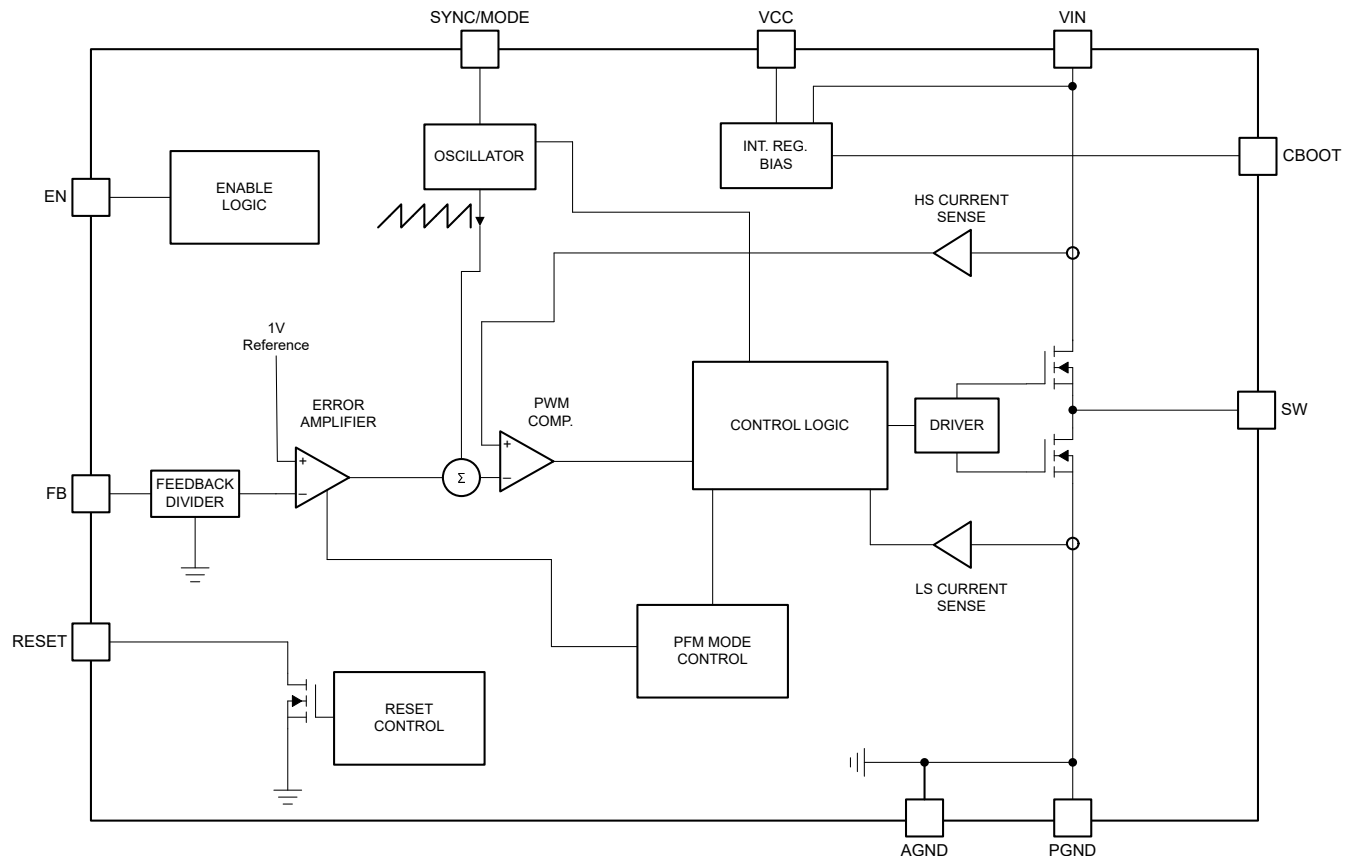
### 7.1 Overview

The LM63635C-Q1 device is a synchronous peak-current-mode buck regulator designed for a wide variety of automotive applications. The regulator automatically switches modes between PFM and PWM, depending on load. At heavy loads, the device operates in PWM at a constant switching frequency. At light loads, the mode changes to PFM with diode emulation, allowing DCM. This action reduces the input supply current and keeps efficiency high. The device features the following:

- Fixed switching frequency at 400kHz or 2.1MHz
- Forced PWM mode (FPWM)
- Frequency synchronization
- Fixed output voltage at 3.3V or 5V

The **RESET** output allows easy system sequencing. In addition, internal compensation reduces design time and requires fewer external components than externally compensated regulators.

### 7.2 Functional Block Diagram



### 7.3 Feature Description

#### 7.3.1 Sync/Mode Selection

The LM63635C-Q1 features selectable operating modes through the SYNC/MODE input. [Table 7-1](#) shows the selection programming. Mode changes can be made *on the fly* anytime after the device is powered up. TI does not recommend that this input be allowed to float, however, an internal 100kΩ pulls the input to ground if left floating. The value of this internal resistor and the logic thresholds for this input can be found in the *Electrical Characteristics*. See [Section 7.4](#) for details of the operating modes.

**Table 7-1. Mode Selection Settings**

SYNC/MODE INPUT	MODE
VCC	FPWM
AGND	AUTO
Synchronizing clock	FPWM; synchronized to external clock
Float (not recommended)	AUTO

### 7.3.2 Output Voltage Selection

The LM63635C-Q1 contains an integrated voltage divider connected to the FB input. The converter regulates the output voltage to 3.3V or 5V depending on the device selected. See [Section 6](#) for ensured specifications regarding the accuracy of the FB voltage and input current to the FB pin.

Providing internal voltage dividers for the 3.3V and 5V modes saves external components, reducing both board space and component cost. The relatively large values of the internal dividers reduce the load on the output, helping to improve the light load efficiency of the converter. In addition, because the divider is inside the device, the divider is less likely to pick up externally generated noise.

### 7.3.3 Switching Frequency Selection

The switching frequency is set based on the device that is selected. The switching frequency is either 400kHz or 2.1MHz. See [Section 4](#) for more information.

#### 7.3.3.1 Spread Spectrum Option

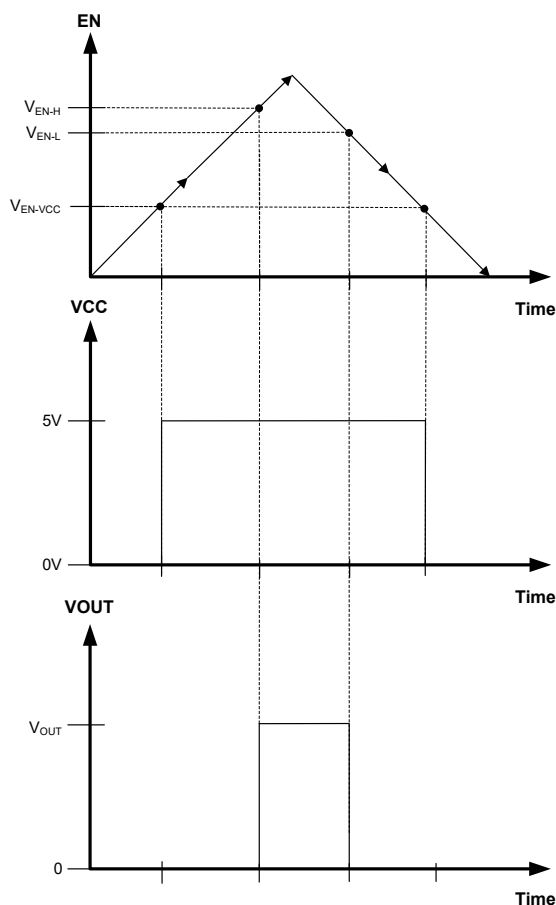
The LM63635C-Q1 is available with a spread spectrum clock dithering feature. This feature uses a pseudo-random pattern to dither the internal clock frequency. The pattern repeats at a 0.98Hz rate while the depth of modulation is  $\pm 5\%$ .

The purpose of the spread spectrum is to eliminate peak emissions at specific frequencies by spreading emissions across a wider range of frequencies than a part with fixed frequency operation. In most systems containing the LM63635C-Q1, low frequency conducted emissions from the first few harmonics of the switching frequency can be easily filtered. A more difficult design criterion is reduction of emissions at higher harmonics which fall in the FM band. These harmonics often couple to the environment through electric fields around the switch node. The LM63635C-Q1 uses a  $\pm 5\%$  spread of frequencies, which spreads energy smoothly across the FM band but is small enough to limit subharmonic emissions below the switching frequency.

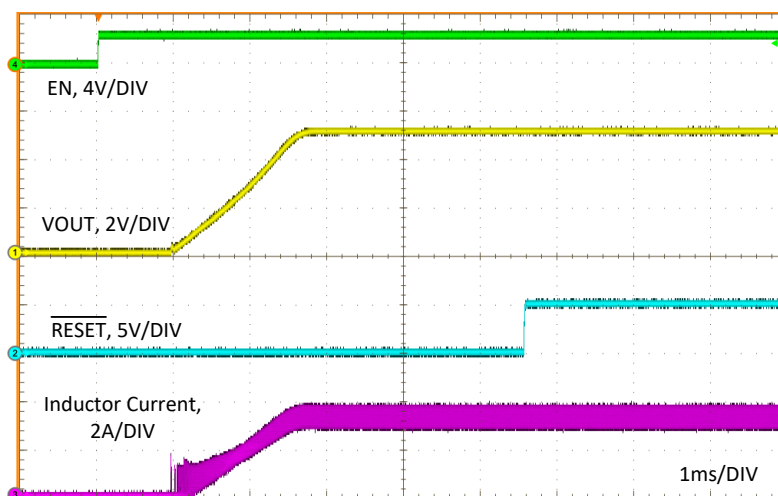
### 7.3.4 Enable and Start-Up

Start-up and shutdown are controlled by the EN input. This input features precision thresholds, allowing the use of an external voltage divider to provide an adjustable input UVLO (see [Section 8.2.2.7](#)). Applying a voltage greater than  $V_{EN-VCC}$  causes the device to enter standby mode, powering the internal VCC, but not producing an output voltage. Increasing the EN voltage to  $V_{EN-H}$  fully enables the device, allowing the device to enter start-up mode and begin the soft-start period. When the EN input is brought below  $V_{EN-L}$ , the regulator stops running and enters standby mode. Further decrease in the EN voltage to below  $V_{EN-VCC}$  completely shuts down the device. [Figure 7-1](#) shows this behavior. The EN input can be connected directly to VIN if this feature is not needed. This input must not be allowed to float. The values for the various EN thresholds can be found in [Section 6](#).

The LM63635C-Q1 uses a reference-based soft start that prevents output voltage overshoots and large inrush currents as the regulator is starting up. [Figure 7-2](#) shows a typical start-up waveform along with typical timings. After the EN goes high, there is a delay of about 1ms before the soft-start period begins. The output voltage begins to rise and reaches the final value in about 1.5ms ( $t_{ss}$ ). After a delay of about 3ms ( $t_{rise-delay}$ ), the RESET flag goes high. This time is measured from the rising edge of EN. TI does not recommend to start up with a prebiased output voltage of greater than 1V.



**Figure 7-1. Precision Enable Behavior**



**Figure 7-2. Typical Start-Up Behavior  $V_{IN} = 12V$ ,  $V_{OUT} = 5V$ ,  $I_{OUT} = 3.25A$**

### 7.3.5 RESET Flag Output

The  $\overline{RESET}$  flag function ( $\overline{RESET}$  output pin) of the LM63635C-Q1 device can be used to reset a system microprocessor whenever the output voltage is out of regulation. This open-drain output goes low under fault

conditions, such as current limit and thermal shutdown, as well as during normal start-up. A glitch filter prevents false flag operation for short excursions of the output voltage, such as during line and load transients. Output voltage excursions lasting less than  $t_{dg}$  do not trip the RESET flag. After the FB voltage has returned to the regulation value and after a delay of  $t_{rise-delay}$ , the RESET flag goes high. RESET operation can best be understood by reference to [Figure 7-3](#) and [Figure 7-4](#).

The RESET output consists of an open-drain NMOS, requiring an external pullup resistor to a logic supply that can be used. The RESET output can also be pulled up to either VCC or V<sub>OUT</sub> through an appropriate resistor, as desired. Pullup resistor values in the range of 10kΩ to 100kΩ are reasonable. If this function is not needed, the RESET pin can be left floating. When EN is pulled low, the flag output is also forced low. With EN low, RESET remains valid as long as the input voltage is ≥ 1.2V (typical). Limit the current into the RESET flag pin to approximately 5mA. The maximum current is internally limited to approximately 50mA when the device is enabled and approximately 65mA when the device is disabled. The internal current limit protects the device from any transient currents that can occur when discharging a filter capacitor connected to this output.

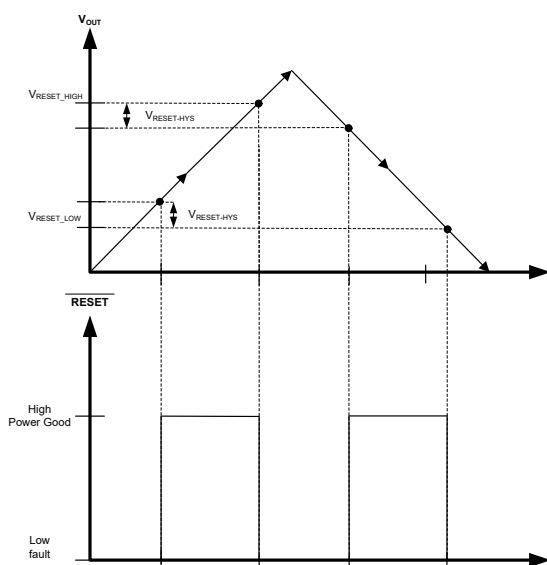


Figure 7-3. Static RESET Operation

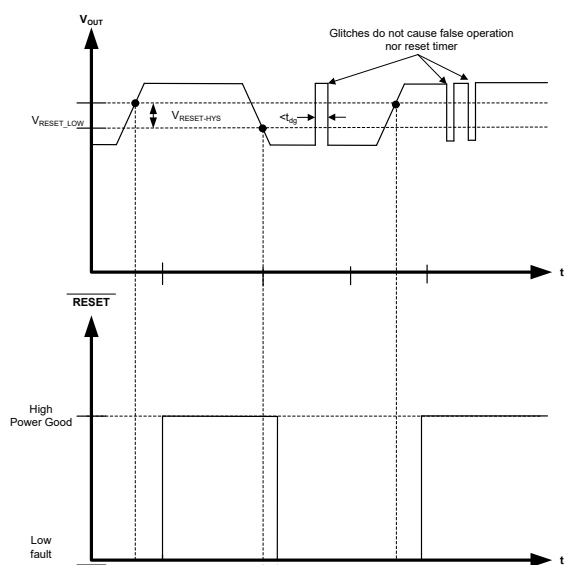


Figure 7-4. RESET Timing Behavior

### 7.3.6 Undervoltage Lockout, Thermal Shutdown, and Output Discharge

The LM63635C-Q1 incorporates an undervoltage lockout feature on the output of the internal LDO (at the VCC pin). When  $V_{IN}$  reaches approximately  $V_{POR-R}$ , the device is ready to receive an EN signal and start up. When  $V_{IN}$  falls below  $V_{POR-F}$ , the device shuts down, regardless of EN status. Because the LDO is in dropout during these transitions, the above values roughly represent the VCC voltage levels during the transitions. An extended input voltage UVLO can also be accomplished as shown in [Section 8.2.2.7](#).

Thermal shutdown is provided to protect the regulator from excessive junction temperature. When the junction temperature reaches about 163°C, the device shuts down; restart occurs when the temperature falls to about 150°C.

The LM63635C-Q1 features an output voltage discharge FET connected from the SW pin to ground. This FET is activated when the EN input is below  $V_{EN-L}$ , or when the output voltage exceeds  $V_{RESET-HIGH}$ . This way, the output capacitors are discharged through the power inductor. At output voltages above about 5V, the discharge current is approximately constant at  $I_{POR}$  or about 1.4mA. Below this voltage, the FET characteristic looks approximately resistive at a value of 2.5kΩ.



## 7.4 Device Functional Modes

### 7.4.1 Overview

In AUTO mode, the device moves between PWM and PFM as the load changes. At light loads, the regulator operates in PFM where the switching frequency is varied to regulate the output voltage. At higher loads, the mode changes to PWM with the switching frequency of the selected device.

In PWM mode, the regulator operates as a current mode, constant frequency converter using PWM to regulate the output voltage. While operating in this mode, the output voltage is regulated by switching at a constant frequency and modulating the duty cycle to control the power to the load. This action provides excellent line and load regulation and low output voltage ripple.

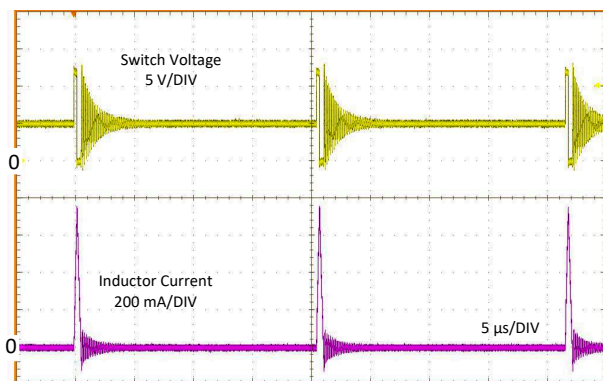
In PFM mode, the high-side MOSFET is turned on in a burst of one or more pulses to provide energy to the load. The duration of the burst depends on how long the inductor current takes to reach  $I_{PEAK-MIN}$ . The periodicity of these bursts is adjusted to regulate the output, while diode emulation (DEM) is used to maximize efficiency (see the [Glossary](#)). This mode provides high light-load efficiency by reducing the amount of input supply current required to regulate the output voltage at small loads. This action trades off very good light-load efficiency for larger output voltage ripple and variable switching frequency. Also, a small increase in output voltage occurs at light loads. See [Section 8.2.3](#) for output voltage variation with load in PFM mode. [Figure 7-5](#) and [Figure 7-6](#) show the typical switching waveforms in PFM and PWM.

There are four cases where the switching frequency does not conform to the condition set by the switching frequency:

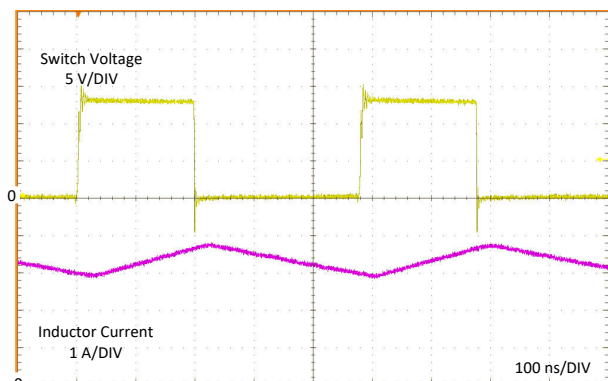
- Light load operation (AUTO mode)
- Dropout
- Minimum on-time operation
- Current limit

Under all of these cases, the switching frequency *folds back*, meaning less than the programmed frequency. During these conditions, by definition, the output voltage remains in regulation, except for current limit operation.

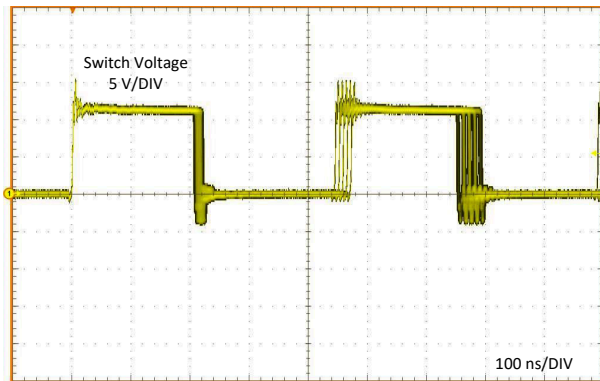
When the device is placed in forced PWM mode (FPWM), the switching frequency remains constant as programmed for the device. This mode essentially turns off the light-load PFM frequency foldback mode detailed in [Section 7.4.2](#). See [Section 7.3.1](#) and [Section 7.4.2.1](#) for details.



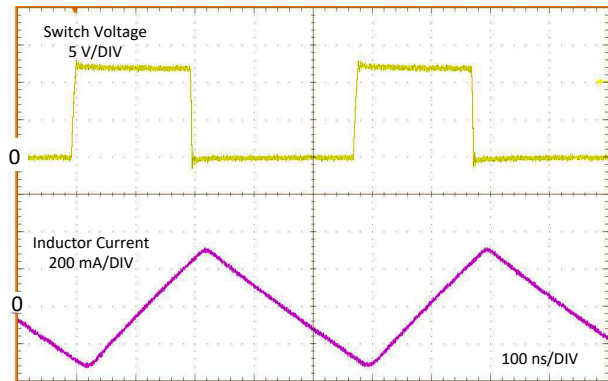
**Figure 7-5. Typical PFM Switching Waveforms  $V_{IN} = 12V$ ,  $V_{OUT} = 5V$ ,  $I_{OUT} = 10mA$**



**Figure 7-6. Typical PWM Switching Waveforms Without Spread Spectrum  $V_{IN} = 12V$ ,  $V_{OUT} = 5V$ ,  $I_{OUT} = 3.25A$ ,  $f_{SW} = 2100kHz$**



**Figure 7-7. Typical PWM Switching Waveforms With Spread Spectrum**  $V_{IN} = 12V$ ,  $V_{OUT} = 5V$ ,  $I_{OUT} = 2.5A$ ,  $f_{SW} = 2100kHz$



**Figure 7-8. Typical PWM Switching Waveforms** **FPWM**  $V_{IN} = 12V$ ,  $V_{OUT} = 5V$ ,  $I_{OUT} = 0A$ ,  $f_{SW} = 2100kHz$

### 7.4.2 Light Load Operation

During light load operation, the device is in PFM mode with DEM. This mode provides high efficiency at the lower load currents. The actual switching frequency and output voltage ripple depend on the input voltage, output voltage, and load. The output current at which the device moves in and out of PFM can be found in [Section 8.2.3](#). The output current for mode change depends on the input voltage, inductor value, and the programmed switching frequency. The curves apply for the BOM shown in [Table 8-1](#). At higher programmed switching frequencies, the load at which the mode change occurs is greater. For applications where the switching frequency must be known for a given condition, the transition between PFM and PWM must be carefully tested before the design is finalized.

#### 7.4.2.1 Sync/FPWM Operation

The forced PWM mode (FPWM) can be used to turn off AUTO mode and force the device to switch at the programmed frequency, even for small loads. This has the disadvantage of lower efficiency at light loads.

When a valid clock signal is present on the SYNC/MODE input, the switching frequency is locked to the external clock. The device mode is also FPWM. The mode can be changed dynamically by the system. See [Figure 7-9](#) for typical examples of SYNC/MODE function changes.

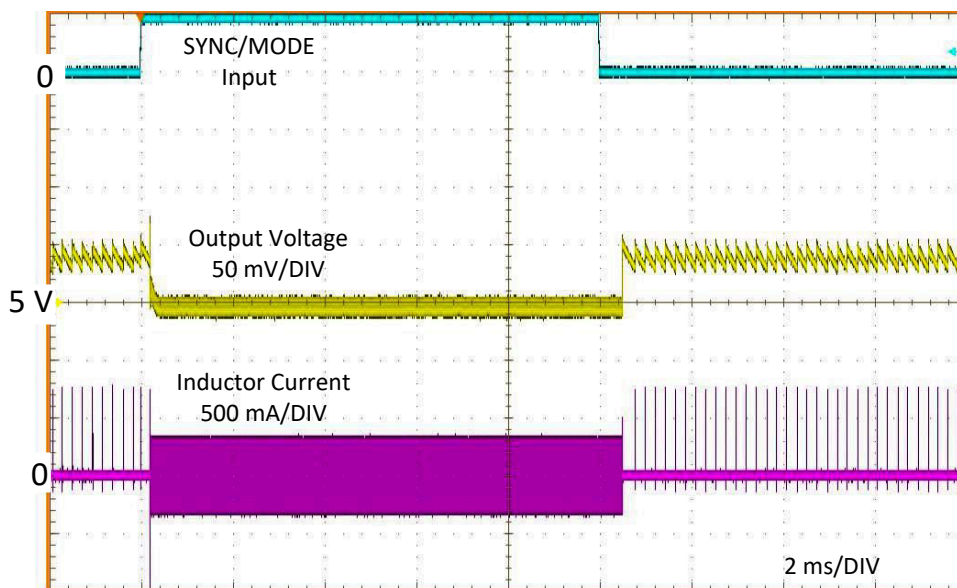


Figure 7-9. Typical Transition from FPWM to AUTO Mode  $V_{IN} = 12V$ ,  $V_{OUT} = 5V$ ,  $I_{OUT} = 1mA$

### 7.4.3 Dropout Operation

The dropout performance of any buck regulator is affected by the  $R_{DS(on)}$  of the power MOSFETs, the DC resistance of the inductor, and the maximum duty cycle that the controller can achieve. As the input voltage level approaches the output voltage, the off-time of the high-side MOSFET starts to approach the minimum value (see Section 6). Beyond this point, the switching can become erratic and the output voltage can fall out of regulation. To avoid this problem, the LM63635C-Q1 automatically reduces the switching frequency to increase the effective duty cycle and maintain regulation. There are two definitions of *dropout* voltage used in this data sheet. For both definitions, the dropout voltage is the difference between the input and output voltage under a specific condition. For the first definition, the difference is taken when the switching frequency has dropped to 1850kHz (this applies to cases where the nominal switching frequency is > 1850kHz). For this condition, the output voltage is within regulation. For the second definition, the difference is taken when the output voltage has fallen by 1% of the nominal regulation value. In this condition, the switching frequency has reached the lower limit of about 130kHz. See Section 8.2.3 for details on these characteristics. Typical overall dropout characteristics can be found in Figure 7-10.

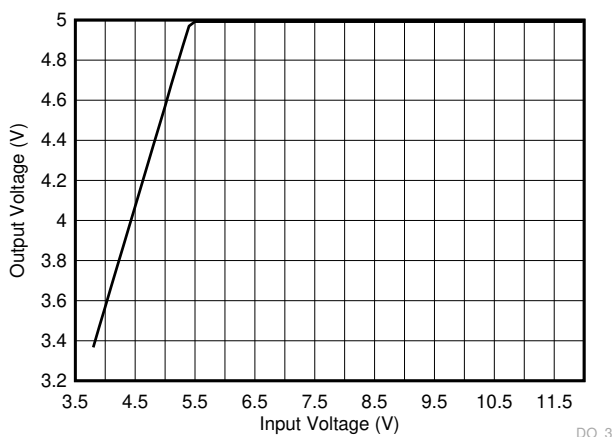


Figure 7-10. Overall Dropout Characteristic  $V_{OUT} = 5V$ ,  $I_{OUT} = 3.25A$

#### 7.4.4 Minimum On-Time Operation

Every switching regulator has a minimum controllable on-time dictated by the inherent delays and blanking times associated with the control circuits. This on-time imposes a minimum switch duty cycle and, therefore, a minimum conversion ratio. The constraint is encountered at high input voltages and low output voltages. To help extend the minimum controllable duty cycle, the LM63635C-Q1 automatically reduces the switching frequency when the minimum on-time limit is reached. This way, the converter can regulate the lowest programmable output voltage at the maximum input voltage. Use Equation 1 to find an estimate for the approximate input voltage for a given output voltage before frequency foldback occurs. The values of  $t_{ON}$  and  $f_{SW}$  can be found in Section 6. As the input voltage is increased, the switch on-time (duty-cycle) reduces to regulate the output voltage. When the on-time reaches the limit, the switching frequency drops while the on-time remains fixed. This relationship is highlighted in  $f_{SW}$  versus  $V_{IN}$  curves in Section 8.2.3.

$$V_{IN} \leq \frac{V_{OUT}}{t_{ON} \times f_{SW}} \quad (1)$$

#### 7.4.5 Current Limit and Short-Circuit Operation

The LM63635C-Q1 incorporates both peak and valley inductor current limits to provide protection to the device from overloads and short circuits and limit the maximum output current. Valley current limit prevents inductor current run-away during short circuits on the output, while both peak and valley limits work together to limit the maximum output current of the converter. A hiccup type mode is also incorporated for sustained short circuits. Finally, a zero current detector is used on the low-side power MOSFET to implement DEM at light loads (see the Glossary). The nominal value of this limit is about 0A.

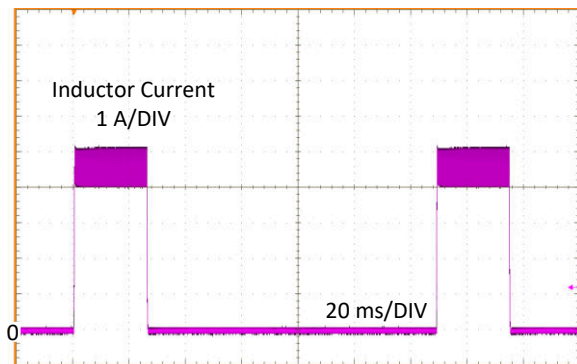
As the device is overloaded, a point is reached where the valley of the inductor current cannot reach below  $I_{LS-LIMIT}$  before the next clock cycle. When this event occurs, the valley current limit control skips that cycle, causing the switching frequency to drop. Further overload causes the switching frequency to continue to drop, but the output voltage remains in regulation. As the overload is increased, both the inductor current ripple and peak current increase until the high-side current limit,  $I_{SC}$ , is reached. When this limit is activated, the switch duty cycle is reduced and the output voltage falls out of regulation. This event represents the maximum output current from the converter and is given approximately by Equation 2. The output voltage and switching frequency continue to drop as the device moves deeper into overload while the output current remains at approximately  $I_{OMAX}$ . If the inductor ripple current is large, the high-side current limit can be tripped before the low-side limit is reached. In this case, Equation 3 gives the approximate maximum output current.

$$I_{OMAX} \approx \frac{I_{SC} + I_{LS-LIMIT}}{2} \quad (2)$$

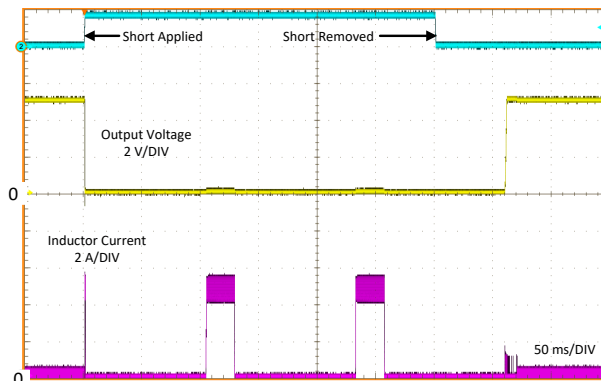
$$I_{OMAX} \approx I_{SC} - \frac{(V_{IN} - V_{OUT})}{2 \times L \times f_{SW}} \times \frac{V_{OUT}}{V_{IN}} \quad (3)$$

If a severe overload or short circuit causes the FB voltage to fall below  $V_{HICCUP}$ , the convert enters hiccup mode.  $V_{HICCUP}$  represents about 40% of the nominal programmed output voltage. In this mode, the device stops switching for  $t_{OC}$ , or about 100ms, and then goes through a normal restart with soft start. If the short-circuit condition remains, the device runs in current limit for a little longer than  $t_{OC\_active}$ , or about 23ms, and then shuts down again. This cycle repeats (as shown in Figure 7-11) as long as the short-circuit condition persists. This mode of operation reduces the temperature rise of the device during a sustained short on the output. The output current in this mode is approximately 20% of  $I_{OMAX}$ . After the output short is removed and the  $t_{OC}$  delay is passed, the output voltage recovers normally as shown in Figure 7-12.

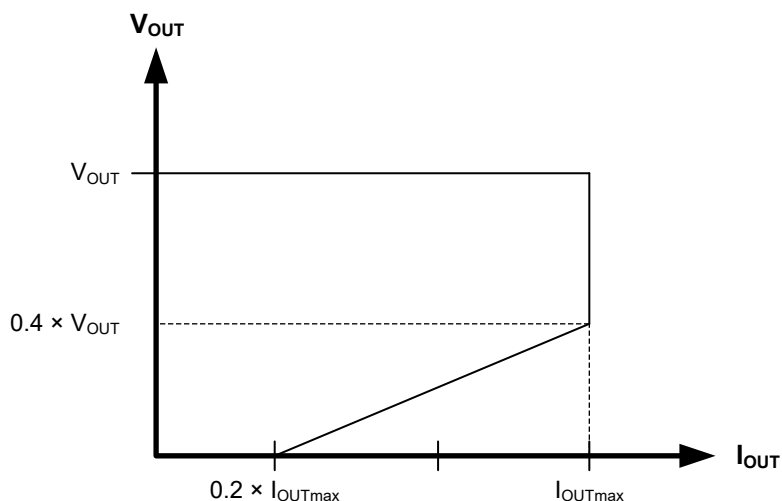
See Figure 7-13 for the overall output voltage versus output current characteristic.



**Figure 7-11. Inductor Current Burst in Short-Circuit Mode**



**Figure 7-12. Short-Circuit Transient and Recovery**



**Figure 7-13. Output Voltage versus Output Current in Current Limit**

## 8 Application and Implementation

### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### 8.1 Application Information

The LM63635C-Q1 step-down DC-to-DC converter is typically used to convert a higher DC voltage to a lower DC voltage with a maximum output current of 3.25A. The following design procedure can be used to select components for the LM63635C-Q1.

### Note

In this data sheet, the *effective* value of capacitance is defined as the actual capacitance under D.C. bias and temperature, not the rated or nameplate values. Use high-quality, low-ESR, ceramic capacitors with an X5R or better dielectric throughout. All high value ceramic capacitors have a large voltage coefficient in addition to normal tolerances and temperature effects. Under D.C. bias, the capacitance drops considerably. Large case sizes and higher voltage ratings are better in this regard. To help mitigate these effects, multiple capacitors can be used in parallel to bring the minimum *effective* capacitance up to the required value. This use can also ease the RMS current requirements on a single capacitor. A careful study of bias and temperature variation of any capacitor bank must be made to make sure that the minimum value of *effective* capacitance is provided.

### 8.2 Typical Application

Figure 8-1 shows a typical application circuit for the LM63635C-Q1. This device is designed to function over a wide range of external components and system parameters. However, the internal compensation is optimized for a certain range of external inductance and output capacitance. As a quick start guide, see Table 8-1 for typical component values.

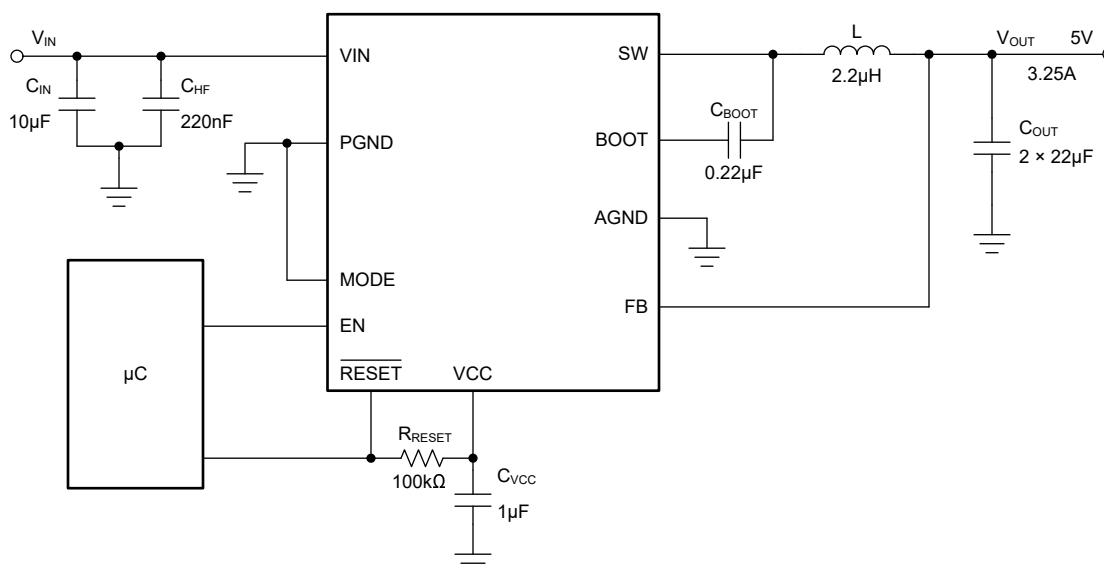


Figure 8-1. Example Application Circuit  $V_{IN} = 12V$ ,  $V_{OUT} = 5V$ ,  $I_{OUT} = 3.25A$ ,  $f_{SW} = 2.1MHz$

**Table 8-1. Typical External Component Values for 3.25A Output Current**

f <sub>sw</sub> (kHz)	V <sub>OUT</sub>	L (μH) <sup>(1)</sup>	TYPICAL <sup>(2)</sup> C <sub>OUT</sub>	MINIMUM <sup>(2)</sup> C <sub>OUT</sub>	C <sub>IN</sub>	C <sub>BOOT</sub>	C <sub>VCC</sub>
400	3.3	10	3 × 22μF	2 × 22μF	10μF + 220nF	220nF	1μF
2100	3.3	2.2	2 × 22μF	1 × 22μF + 1 × 10μF	10μF + 220nF	220nF	1μF
400	5	10	3 × 22μF	2 × 22μF	10μF + 220nF	220nF	1μF
2100	5	2.2	2 × 22μF	1 × 22μF + 1 × 10 μF	10μF + 220nF	220nF	1μF

(1) See the [Section 8.2.2.2](#).

(2) See the [Section 8.2.2.3](#).

## 8.2.1 Design Requirements

[Table 8-2](#) provides the parameters for the detailed design procedure:

**Table 8-2. Detailed Design Parameters**

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage	12V (6V to 32V)
Output voltage	5V
Maximum output current	0A to 3.25A
Switching frequency	2.1MHz

## 8.2.2 Detailed Design Procedure

The following design procedure applies to [Figure 8-1](#) and [Table 8-2](#).

### 8.2.2.1 Choosing the Switching Frequency

The choice of switching frequency is a compromise between conversion efficiency and overall design size. Lower switching frequency implies reduced switching losses and usually results in higher system efficiency. However, higher switching frequency allows the use of smaller inductors and output capacitors, and hence, a more compact design. There are several options to set the switching frequency of the LM63635C-Q1. The internal switching frequency is set at 400kHz or 2.1MHz. For the application example, the switching frequency F<sub>sw</sub> was chosen to be 2.1MHz.

### 8.2.2.2 Inductor Selection

The parameters for selecting the inductor are the inductance and saturation current. The inductance is based on the desired peak-to-peak ripple current and is normally chosen to be in the range of 20% to 40% of the maximum output current. Experience shows that the best value for inductor ripple current is 30% of the maximum load current. Larger values of ripple current can restrict the maximum output current, before current limit is reached. This trade-off can be examined with the help of [Equation 2](#) and the ensured current limits found in [Section 6](#). Smaller values of ripple current reduce the SNR of the current mode controller and can lead to increased jitter in the duty cycle. Both the inductor and switching frequency tolerance have an impact on the selection of ripple current, and, therefore, inductor value. Use the maximum device current when calculating the ripple current for applications with much smaller maximum load than the maximum available from the device. The ratio of inductor ripple current over maximum output current is designated as K in the following equations. [Equation 4](#) can be used to determine the value of inductance. K = 0.2 was chosen for this example and L = 2.1μH inductance was found. A standard value of 2.2μH was selected. This gives a new K = 0.19.

$$L = \frac{(V_{IN} - V_{OUT})}{f_{SW} \times K \times I_{OUTmax}} \times \frac{V_{OUT}}{V_{IN}} \quad (4)$$

Ideally, the saturation current rating of the inductor is at least as large as the high-side switch current limit, I<sub>SC</sub> (see [Section 6](#)). This size makes sure that the inductor does not saturate even during a short circuit on the output. When the inductor core material saturates, the inductance falls to a very low value, causing the inductor current to rise very rapidly. Although the valley current limit, I<sub>LIMIT</sub>, is designed to reduce the risk of current run-away, a saturated inductor can cause the current to rise to high values very rapidly. This can lead



to component damage. Do not allow the inductor to saturate. Inductors with a ferrite core material have very *hard* saturation characteristics, but usually have lower core losses than powdered iron cores. Powered iron cores exhibit a *soft* saturation, allowing some relaxation in the current rating of the inductor. However, powered iron cores have more core losses at frequencies above about 1MHz. In any case, the inductor saturation current must not be less than the maximum peak inductor current at full load.

To avoid subharmonic oscillation, the inductance value must not be less than that given in [Equation 5](#). The maximum inductance is limited by the minimum current ripple required for the current mode control to perform correctly. As a rule-of-thumb, the minimum inductor ripple current must be no less than about 10% of the device maximum rated current under nominal conditions.

$$L_{\text{MIN}} \geq M \times \frac{V_{\text{OUT}}}{f_{\text{SW}}} \quad (5)$$

where

- $M = 0.37$  for 3.25A device

### 8.2.2.3 Output Capacitor Selection

The value of the output capacitor and the ESR determine the output voltage ripple and load transient performance. The output capacitor bank is usually limited by the load transient requirements rather than the output voltage ripple. Use [Equation 6](#) to estimate a lower bound on the total output capacitance, and an upper bound on the ESR, which are required to meet a specified load transient.

$$\begin{aligned} C_{\text{OUT}} &\geq \frac{\Delta I_{\text{OUT}}}{f_{\text{SW}} \times \Delta V_{\text{OUT}} \times K} \times \left[ (1-D) \times (1+K) + \frac{K^2}{12} \times (2-D) \right] \\ \text{ESR} &\leq \frac{(2+K) \times \Delta V_{\text{OUT}}}{2 \times \Delta I_{\text{OUT}} \times \left[ 1+K + \frac{K^2}{12} \times \left( 1 + \frac{1}{(1-D)} \right) \right]} \\ D &= \frac{V_{\text{OUT}}}{V_{\text{IN}}} \end{aligned} \quad (6)$$

where

- $\Delta V_{\text{OUT}}$  = output voltage transient
- $\Delta I_{\text{OUT}}$  = output current transient
- $K$  = ripple factor from [Section 8.2.2.2](#)

After the output capacitor and ESR have been calculated, use [Equation 7](#) to check the peak-to-peak output voltage ripple,  $V_r$ .

$$V_r \cong \Delta I_L \times \sqrt{\text{ESR}^2 + \frac{1}{(8 \times f_{\text{SW}} \times C_{\text{OUT}})^2}} \quad (7)$$

The output capacitor and ESR can then be adjusted to meet both the load transient and output ripple requirements.

This example requires a  $\Delta V_{\text{OUT}}$  of  $\leq 200\text{mV}$  for an output current step of  $\Delta I_{\text{OUT}} = 3.25\text{A}$ . [Equation 6](#) gives a minimum value of  $28\mu\text{F}$  and a maximum ESR of  $0.056\Omega$ . Assuming a 20% tolerance and a 10% bias derating, the user arrives at a minimum capacitance of  $39\mu\text{F}$ . This capacitance can be achieved with a bank of  $2 \times 22\mu\text{F}$ , 16V, ceramic capacitors in the 1210 case size. More output capacitance can be used to improve the load transient response. Ceramic capacitors can easily meet the minimum ESR requirements. In some cases, an aluminum electrolytic capacitor can be placed in parallel with the ceramics to build up the required value of capacitance. When using a mixture of aluminum and ceramic capacitors, use the minimum recommended value of ceramics and add aluminum electrolytic capacitors as needed.

In general, use a capacitor rating of at least 10V for output voltages of 3.3V or less, and use a capacitor of 16V or more for output voltages of 5V and above.



The recommendations given in [Table 8-1](#) provide typical and minimum values of output capacitance for the given conditions. These values are the rated or nameplate figures. If the minimum values are to be used, the design must be tested over all of the expected application conditions, including input voltage, output current, and ambient temperature. This testing must include both bode plot and load transient assessments. The maximum value of total output capacitance must be limited to about 10 times the design value, or 1000μF, whichever is smaller. Large values of output capacitance can adversely affect the start-up behavior of the regulator as well as the loop stability. If values larger than noted here must be used, then a careful study of start-up at full load and loop stability must be performed.

In practice, the output capacitor has the most influence on the transient response and loop phase margin. Load transient testing and bode plots are the best way to validate any given design and must always be completed before the application goes into production. In addition to the required output capacitance, a small ceramic placed on the output can reduce high frequency noise. Small case size ceramic capacitors in the range of 1nF to 100nF can help reduce spikes on the output caused by inductor and board parasitics.

#### 8.2.2.4 Input Capacitor Selection

The ceramic input capacitors provide a low impedance source to the regulator in addition to supplying the ripple current and isolating switching noise from other circuits. A minimum of 4.7μF of ceramic capacitance is required on the input of the LM63635C-Q1, connected directly between VIN and PGND. This must be rated for at least the maximum input voltage that the application requires; preferably twice the maximum input voltage. This capacitance can be increased to help reduce input voltage ripple and maintain the input voltage during load transients. More input capacitance is required for larger output currents. In addition, a small case size, 220nF ceramic capacitor must be used at the input as close as possible to the regulator, typically within 1mm of the VIN and PGND pins. This placement provides a high frequency bypass for the control circuits internal to the device. For this example, a 10μF, 50V, X7R (or better) ceramic capacitor is chosen. Two 4.7μF capacitors can also be used. The 220nF must also be rated at 50V with an X7R dielectric and preferably a small case size, such as an 0603.

Many times, Using an electrolytic capacitor on the input in parallel with the ceramics is desirable. This statement is especially true if long leads or traces are used to connect the input supply to the regulator. The moderate ESR of this capacitor can help damp any ringing on the input supply caused by the long power leads. The use of this additional capacitor also helps with voltage dips caused by input supplies with unusually high impedance.

Most of the input switching current passes through the ceramic input capacitor or capacitors. Use [Equation 8](#) to calculate the approximate RMS current. Check this value against the manufacturer maximum ratings.

$$I_{RMS} \cong \frac{I_{OUT}}{2} \quad (8)$$

The input capacitor is part of the buck converter high di/dt current loop. The high di/dt current, together with excessive parasitic inductance between the IC and the input capacitor, can result in excessive voltage ringing on the SW node of the IC. The placement of the input capacitor on the board is critical for minimizing the parasitic inductance in the high di/dt loop and accordingly minimizing the SW node ringing at each switching.

For designs targeting the maximum operating voltage of the regulator, make sure that the ringing on the SW node must not exceed the absolute maximum rating of the device. The SW node ringing is a function of how well the input capacitor is positioned with respect to the IC. Refer to the PCB layout examples in [Layout Example](#) for proper placement of the input capacitors.

#### 8.2.2.5 C<sub>BOOT</sub>

The LM63635C-Q1 requires a bootstrap capacitor to be connected between the BOOT pin and the SW pin. This capacitor stores energy that is used to supply the gate drivers for the power MOSFETs. A high-quality ceramic capacitor of 220nF and at least 16V is required.

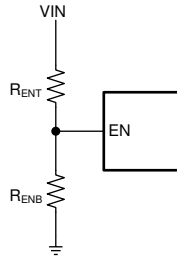
#### 8.2.2.6 VCC

The VCC pin is the output of the internal LDO used to supply the control circuits of the regulator. This output requires a 1μF, 16V ceramic capacitor connected from VCC to PGND for proper operation. In general, this

output must not be loaded with any external circuitry. However, this output can be used to supply the pullup for the RESET function and as a logic supply for the various control inputs of the device. A value of 100kΩ is a good choice for the RESET flag pullup resistor. The nominal output voltage on VCC is 5V.

### 8.2.2.7 External UVLO

In some cases, an input UVLO level different than that provided internal to the device is needed. This need can be accomplished by using the circuit shown in [Figure 8-2](#). The input voltage at which the device turns on is designated as  $V_{ON}$  while the turnoff voltage is  $V_{OFF}$ . First, a value for  $R_{ENB}$  is chosen in the range of 10kΩ to 100kΩ. Then, use [Equation 9](#) to calculate  $R_{ENT}$  and  $V_{OFF}$ .



**Figure 8-2. Setup for External UVLO Application**

$$R_{ENT} = R_{ENB} \times \left( \frac{V_{ON}}{V_{EN-H}} - 1 \right) \quad (9)$$

$$V_{OFF} = V_{EN-L} \times \left( \frac{V_{ON}}{V_{EN-H}} \right)$$

where

- $V_{ON} = V_{IN}$  turn-on voltage
- $V_{OFF} = V_{IN}$  turn-off voltage

### 8.2.2.8 Maximum Ambient Temperature

As with any power conversion device, the LM63635C-Q1 dissipates internal power while operating. The effect of this power dissipation is to raise the internal temperature of the converter above ambient. The internal die temperature ( $T_J$ ) is a function of the ambient temperature, the power loss, and the effective thermal resistance,  $R_{\theta JA}$ , of the device, and PCB combination. The maximum internal die temperature for the LM63635C-Q1 must be limited to 150°C. This limit establishes a limit on the maximum device power dissipation and, therefore, the load current. [Equation 10](#) shows the relationships between the important parameters. Seeing that larger ambient temperatures ( $T_A$ ) and larger values of  $R_{\theta JA}$  reduce the maximum available output current is easy. The converter efficiency can be estimated by using the curves provided in this data sheet. Note that these curves include the power loss in the inductor. If the desired operating conditions cannot be found in one of the curves, then interpolation can be used to estimate the efficiency. Alternatively, the EVM can be adjusted to match the desired application requirements and the efficiency can be measured directly. The correct value of  $R_{\theta JA}$  is more difficult to estimate. As stated in the [Semiconductor and IC Package Thermal Metrics application note](#), the value of  $R_{\theta JA}$  given in the [Section 6.4](#) table is not valid for design purposes and must not be used to estimate the thermal performance of the application. The values reported in that table were measured under a specific set of conditions that are rarely obtained in an actual application. The data given for  $R_{\theta JC(bott)}$  and  $\Psi_{JT}$  can be useful when determining thermal performance. See the [Semiconductor and IC Package Thermal Metrics application report](#) for more information and the resources given at the end of this section.

$$I_{OUTmax} = \frac{(T_J - T_A)}{R_{\theta JA}} \times \frac{\eta}{(1 - \eta)} \times \frac{1}{V_{OUT}} \quad (10)$$

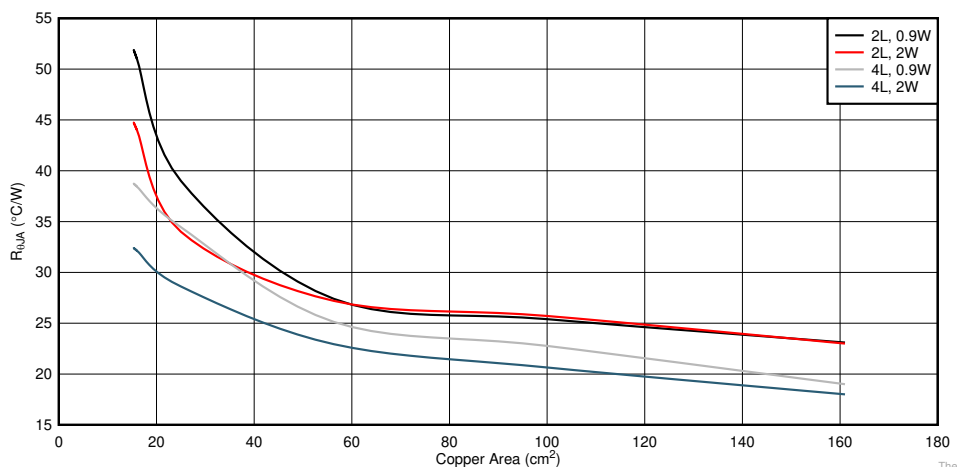
where

- $\eta$  = efficiency

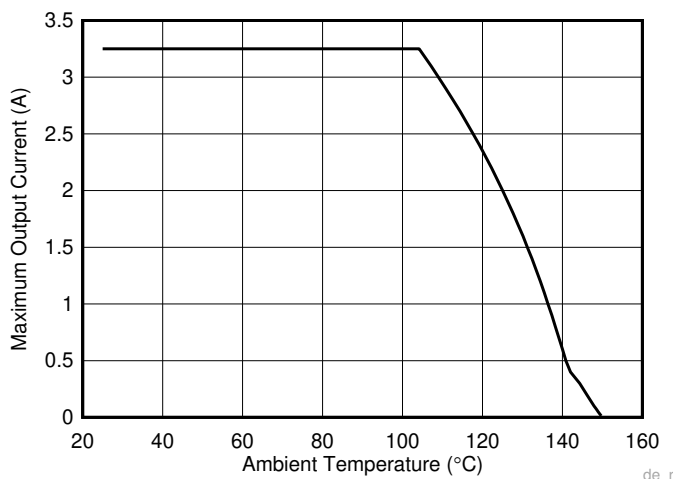
The effective  $R_{\theta JA}$  is a critical parameter and depends on many factors such as the following:

- Power dissipation
- Air temperature and flow
- PCB area
- Copper heat-sink area
- Number of thermal vias under the package
- Adjacent component placement

The WSON12 package uses a die attach paddle, or "thermal pad" (DAP), to provide a place to solder down to the PCB heat-sinking copper. This usage provides a good heat conduction path from the regulator junction to the heat sink and must be properly soldered to the PCB heat sink copper. Typical examples of  $R_{\theta JA}$  versus copper board area can be found in Figure 8-3. The copper area given in the graph is for each layer. The top and bottom layers are 2oz copper each, while the inner layers are 1 oz. Figure 8-4 shows a typical curve of maximum output current versus ambient temperature. This data was taken with a device and PCB combination, giving an  $R_{\theta JA}$  of approximately 22°C/W. Remember that the data given in these graphs are for illustration purposes only, and the actual performance in any given application depends on all of the previously mentioned factors.



**Figure 8-3. Typical  $R_{\theta JA}$  vs Copper Area for the WSON Package**



**Figure 8-4. Maximum Output Current versus Ambient Temperature  $V_{IN} = 12V$ ,  $V_{OUT} = 5V$ ,  $f_{SW} = 400kHz$ ,  $R_{\theta JA} = 22^{\circ}C/W$**

The following resources can be used as a guide to excellent thermal PCB design and estimating  $R_{\theta JA}$  for a given application environment:

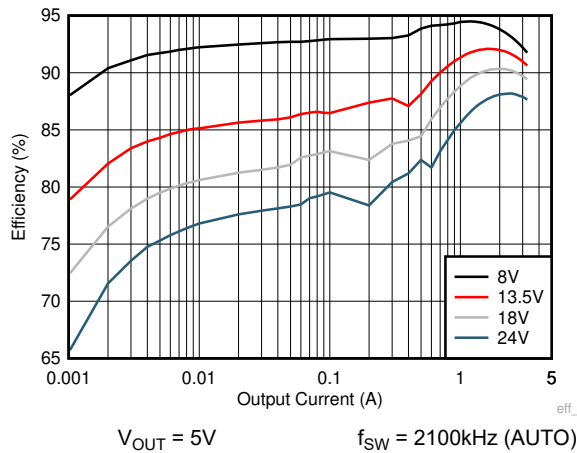
**LM63635C-Q1**SNVSCO0A – JANUARY 2024 – REVISED MAY 2025

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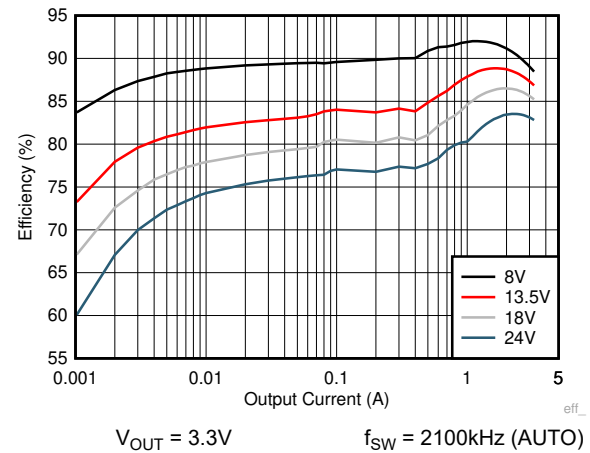
- [AN-2020 Thermal Design By Insight, Not Hindsight](#) application report
- [A Guide to Board Layout for Best Thermal Resistance for Exposed Pad Packages](#) application report
- [Semiconductor and IC Package Thermal Metrics](#) application report
- [Thermal Design Made Simple with LM43603 and LM43602](#) application report
- [Using New Thermal Metrics](#) application report

### 8.2.3 Application Curves

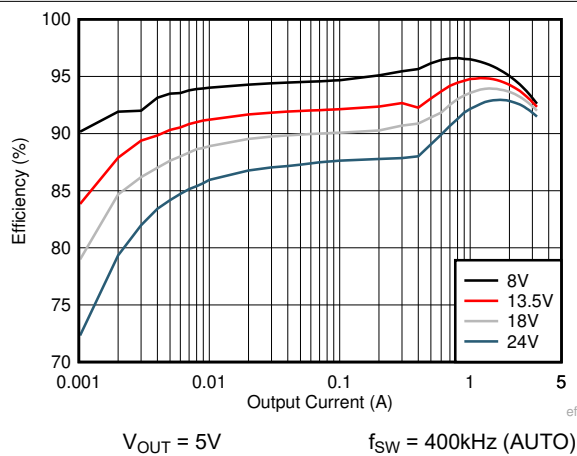
Unless otherwise specified, the following conditions apply:  $V_{IN} = 13.5V$ ,  $T_A = 25^\circ C$ . Figure 8-1 shows the circuit with the appropriate BOM from Table 8-1.



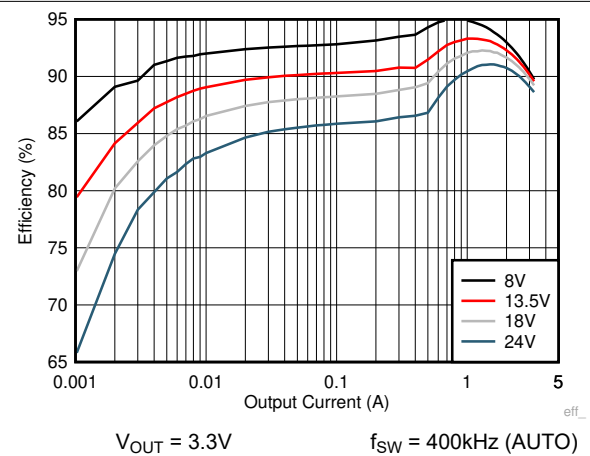
**Figure 8-5. Efficiency**



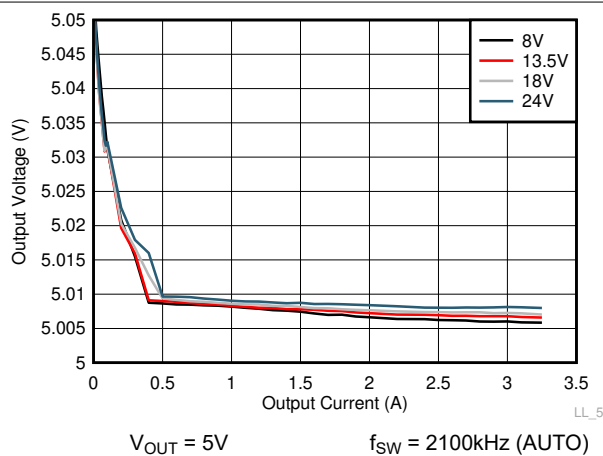
**Figure 8-6. Efficiency**



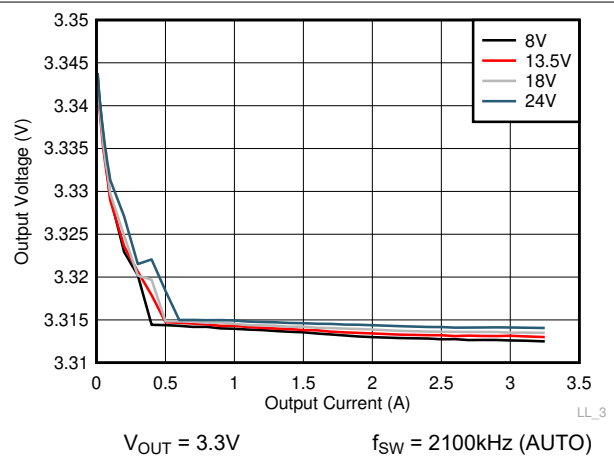
**Figure 8-7. Efficiency**



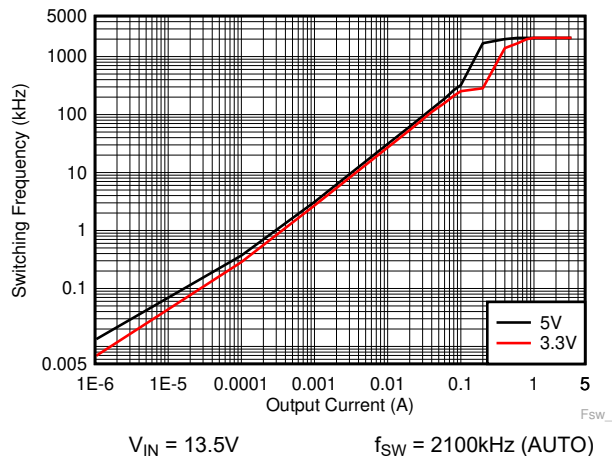
**Figure 8-8. Efficiency**



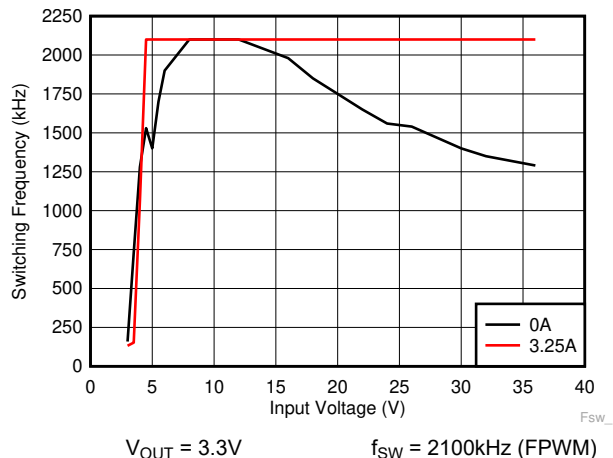
**Figure 8-9. Line and Load Regulation**



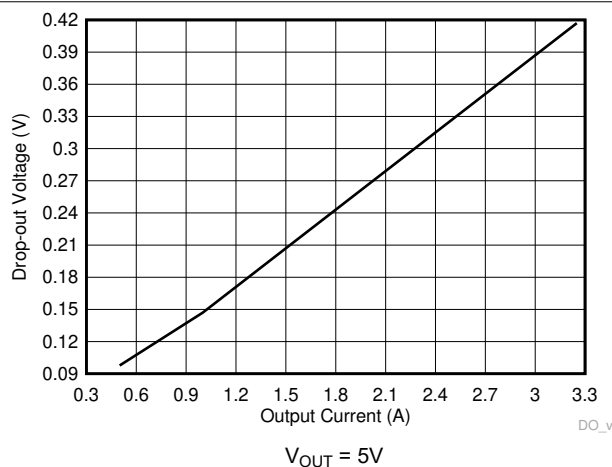
**Figure 8-10. Line and Load Regulation**



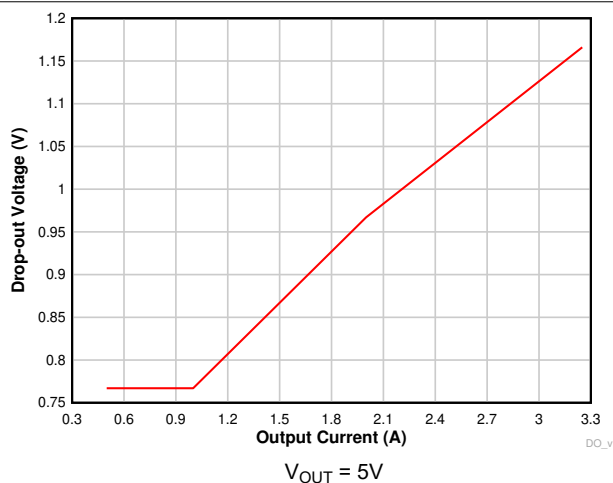
**Figure 8-11. Switching Frequency versus Output Current**



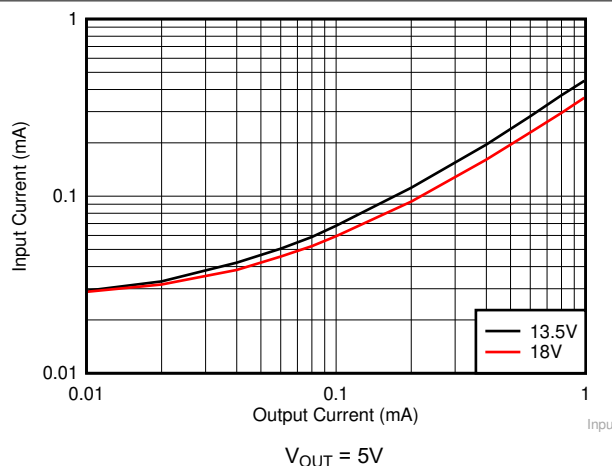
**Figure 8-12. Switching Frequency vs Input Voltage**



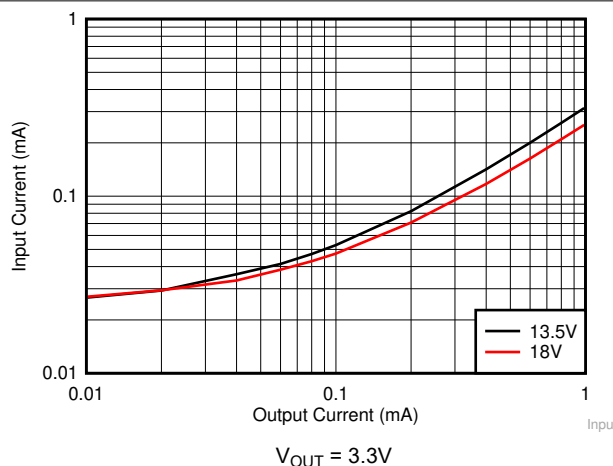
**Figure 8-13. Dropout Voltage versus Output Current for -1% Drop**



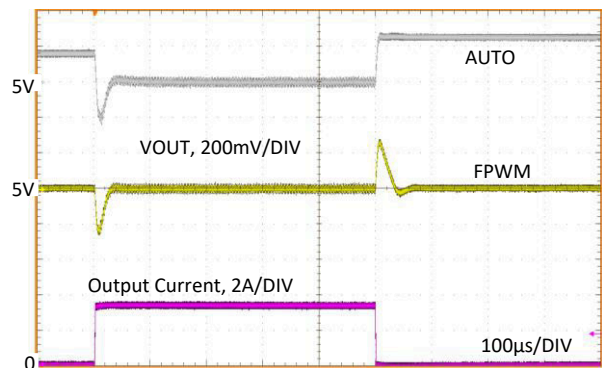
**Figure 8-14. Dropout Voltage versus Output Current to 1.85MHz**



**Figure 8-15. Input Supply Current versus Output Current**

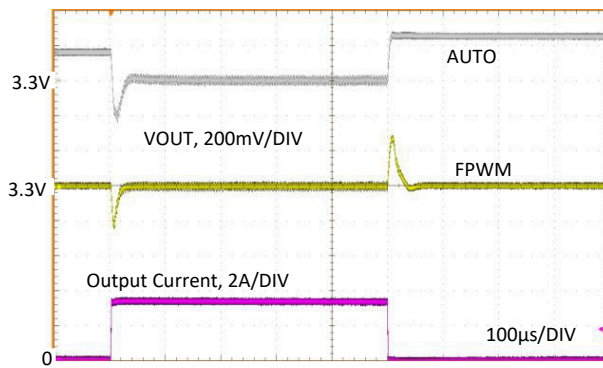


**Figure 8-16. Input Supply Current versus Output Current**



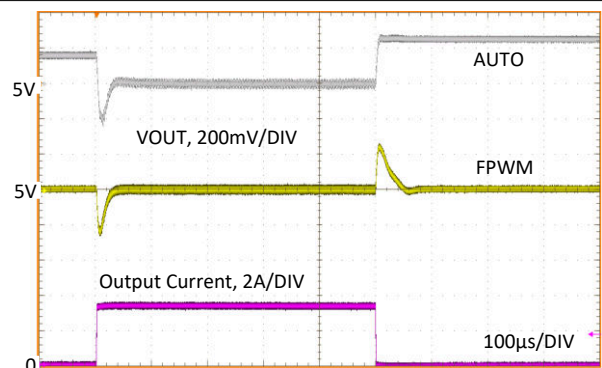
0A to 3.25A, 2μs  $V_{OUT} = 5V$   $f_{SW} = 400kHz$

**Figure 8-17. Load Transient**



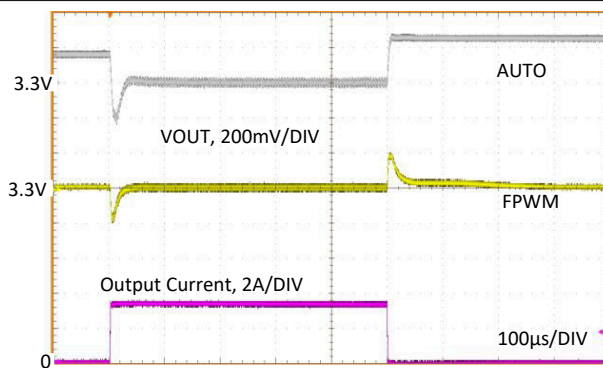
0A to 3.25A, 2μs  $V_{OUT} = 3.3V$   $f_{SW} = 400kHz$

**Figure 8-18. Load Transient**



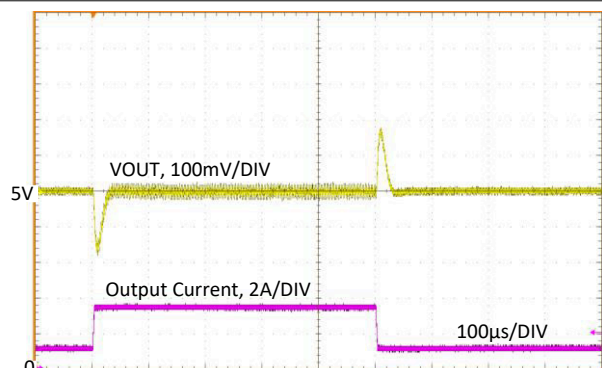
0A to 3.25A, 2μs  $V_{OUT} = 5V$   $f_{SW} = 2100kHz$

**Figure 8-19. Load Transient**



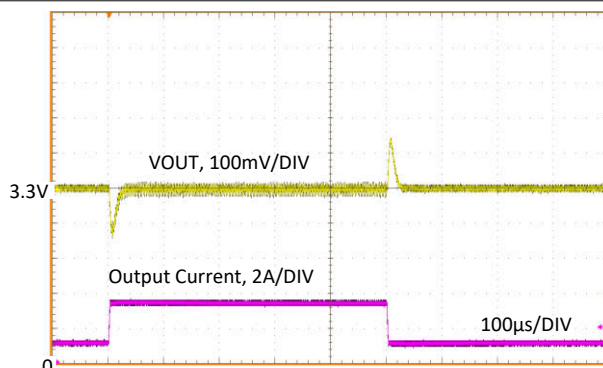
0A to 3.25A, 2μs  $V_{OUT} = 3.3V$   $f_{SW} = 2100kHz$

**Figure 8-20. Load Transient**



$V_{OUT} = 5V$   $f_{SW} = 400kHz$   
AUTO 1A to 3.25A, 2μs

**Figure 8-21. Load Transient**

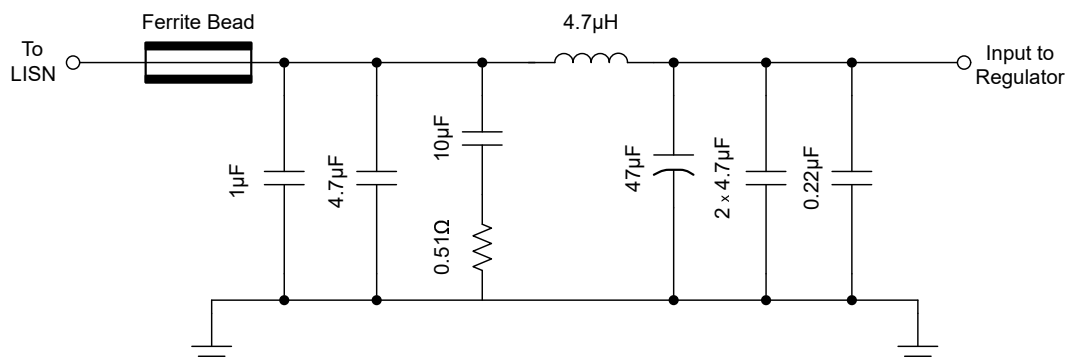
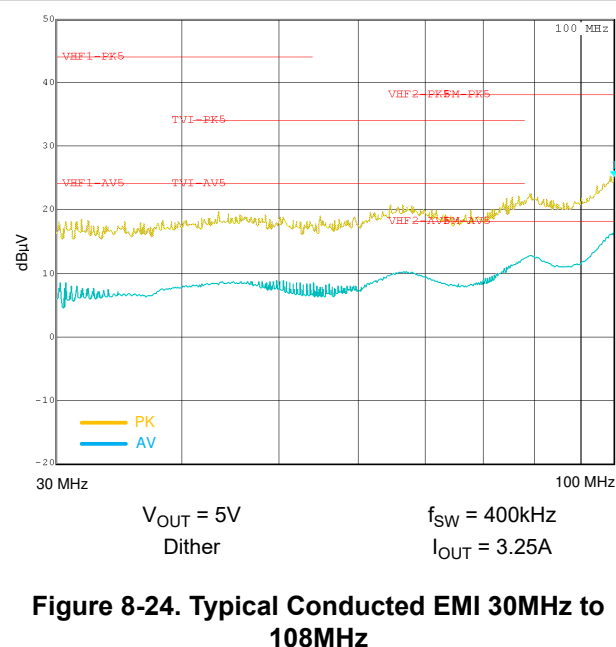
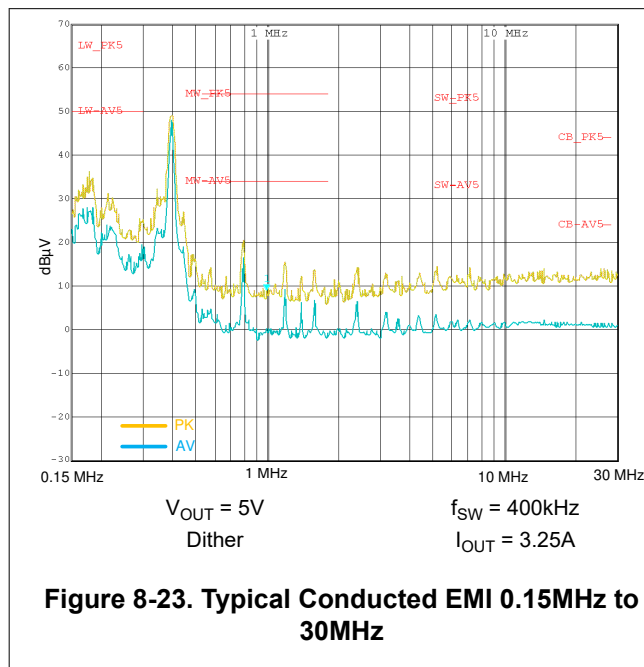


$V_{OUT} = 3.3V$   $f_{SW} = 400kHz$   
AUTO 1A to 3.25A, 2μs

**Figure 8-22. Load Transient**

### 8.2.4 EMI Performance Curves

EMI results critically depend on PCB layout and test setup. The results given here are typical and given for information purposes only. Figure 8-25 shows the used EMI filter. The limit lines shown refer to CISPR25 class 5.



A. Input filter used only for EMI measurements shown in [Section 8.2.4](#).

**Figure 8-25. Typical Input EMI Filter**

### 8.3 Best Design Practices

- Do not exceed the [Absolute Maximum Ratings](#).
- Do not exceed the [Recommended Operating Conditions](#).
- Do not exceed the [ESD Ratings](#).
- Do not allow the EN input to float.
- Do not allow the output voltage to exceed the input voltage, nor go below ground.
- Do not use the value of  $R_{\theta JA}$  given in the [Thermal Information](#) table to design your application. See [Section 8.2.2.8](#).
- Follow all the guidelines and suggestions found in this data sheet before committing the design to production. TI application engineers are ready to help critique your design and PCB layout to help make your project a success.
- Use a 220nF capacitor connected directly to the VIN and PGND pins of the device. See [Section 8.2.2.4](#) for details.



## 8.4 Power Supply Recommendations

The characteristics of the input supply must be compatible with the limits found in [Section 6](#) of this data sheet. In addition, the input supply must be capable of delivering the required input current to the loaded regulator. Estimate the average input current with [Equation 11](#).

$$I_{IN} = \frac{V_{OUT} \times I_{OUT}}{V_{IN} \times \eta} \quad (11)$$

where

- $\eta$  is the efficiency

If the regulator is connected to the input supply through long wires or PCB traces, special care is required to achieve good performance. The parasitic inductance and resistance of the input cables can have an adverse effect on the operation of the regulator. The parasitic inductance, in combination with the low-ESR, ceramic input capacitors, can form an under-damped resonant circuit, resulting in overvoltage transients at the input to the regulator. The parasitic resistance can cause the voltage at the VIN pin to dip whenever a load transient is applied to the output. If the application is operating close to the minimum input voltage, this dip can cause the regulator to momentarily shutdown and reset. The best way to solve these kind of issues is to reduce the distance from the input supply to the regulator and use an aluminum or tantalum input capacitor in parallel with the ceramics. The moderate ESR of these types of capacitors help damp the input resonant circuit and reduce any overshoots. A value in the range of 20µF to 100µF is usually sufficient to provide input damping and help hold the input voltage steady during large load transients.

TI recommends that the input supply must not be allowed to fall below the output voltage by more than 0.3V. Under such conditions, the output capacitors discharges through the body diode of the high-side power MOSFET. The resulting current can cause unpredictable behavior, and in extreme cases, possible device damage. If the application allows for this possibility, then use a Schottky diode from VIN to VOUT to provide a path around the regulator for this current.

In some cases, a transient voltage suppressor (TVS) is used on the input of regulators. One class of this device has a *snap-back* characteristic (thyristor type). TI does not recommend the use of a device with this type of characteristic. When the TVS fires, the clamping voltage falls to a very low value. If this voltage is less than the output voltage of the regulator, the output capacitors discharges through the device, as mentioned above.

Sometimes, for other system considerations, an input filter is used in front of the regulator. This use can lead to instability as well as some of the effects mentioned above, unless designed carefully. The [AN-2162 Simple Success with Conducted EMI from DCDC Converters application report](#) provides helpful suggestions when designing an input filter for any switching regulator.

## 8.5 Layout

### 8.5.1 Layout Guidelines

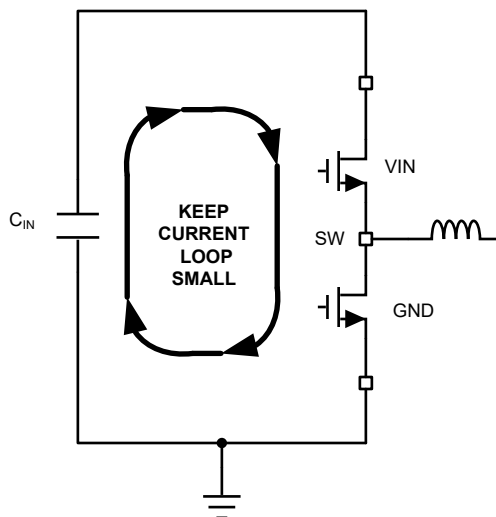
The PCB layout of any DC/DC converter is critical to the optimal performance of the design. Bad PCB layout can disrupt the operation of an otherwise good schematic design. Even if the converter regulates correctly, bad PCB layout can mean the difference between a robust design and one that cannot be mass produced. Furthermore, the EMI performance of the regulator is dependent on the PCB layout to a great extent. In a buck converter, the most critical PCB feature is the loop formed by the input capacitors and power ground, as shown in [Figure 8-26](#). This loop carries large transient currents that can cause large transient voltages when reacting with the trace inductance. These unwanted transient voltages disrupt the proper operation of the converter. Because of this disruption, the traces in this loop must be wide and short, and the loop area as small as possible to reduce the parasitic inductance. [Figure 8-27](#) shows a recommended layouts for the critical components of the LM63635C-Q1.

1. *Place the input capacitors as close as possible to the VIN and PGND terminals.* VIN and PGND pins are adjacent, simplifying the input capacitor placement. TI does not recommend thermal reliefs in this area.
2. *Place a bypass capacitor for VCC close to the VCC pin.* Place this capacitor close to the device and routed with short, wide traces to the VCC and PGND pins. TI does not recommend thermal reliefs in this area.

3. *Use wide traces for the  $C_{BOOT}$  capacitor.* Place  $C_{BOOT}$  close to the device with short and wide traces to the BOOT and SW pins. TI does not recommend thermal reliefs in this area.
4. *Place the feedback divider as close as possible to the FB pin of the device.* If an external feedback divider is used with the ADJ option, place  $R_{FBB}$ ,  $R_{FBT}$ , and  $C_{FF}$  close to the device. The connections to FB and AGND must be short and close to those pins on the device. The connection to  $V_{OUT}$  can be somewhat longer. However, this latter trace must not be routed near any noise source (such as the SW node) that can capacitively couple into the feedback path of the regulator.
5. *Use at least one ground plane in one of the middle layers.* This plane acts as a noise shield and also act as a heat dissipation path.
6. *Connect the thermal pad to the ground plane.* The thermal pad (DAP) connection must be soldered down to the PCB ground plane. This pad acts as a heat-sink connection and an electrical ground connection for the regulator. The integrity of this solder connection has a direct bearing on the total effective  $R_{\theta JA}$  of the application. TI does not recommend thermal reliefs in this area.
7. *Provide wide paths for VIN, VOUT, SW, and PGND.* Making these paths as wide and direct as possible reduces any voltage drops on the input or output paths of the converter and maximizes efficiency. TI does not recommend thermal reliefs in this area.
8. *Provide enough PCB area for proper heat-sinking.* As stated in [Section 8.2.2.8](#), enough copper area must be used to make sure of a low  $R_{\theta JA}$ , commensurate with the maximum load current and ambient temperature. The top and bottom PCB layers must be made with 2oz copper and no less than one ounce. Use an array of heat-sinking vias to connect the thermal pad (DAP) to the ground plane on the bottom PCB layer. If the PCB design uses multiple copper layers (recommended), these thermal vias can also be connected to the inner layer heat-spreading ground planes.
9. *Keep switch area small.* Keep the copper area connecting the SW pin to the inductor as short and wide as possible. At the same time, the total area of this node must be minimized to help reduce radiated EMI.

See the following PCB layout resources for additional important guidelines:

- [Layout Guidelines for Switching Power Supplies application report](#)
- [Simple Switcher PCB Layout Guidelines Application Report](#)
- [Construction Your Power Supply- Layout Considerations seminar](#)
- [Low Radiated EMI Layout Made Simple with LM4360x and LM4600x application report](#)



**Figure 8-26. Current Loops With Fast Edges**

#### 8.5.1.1 Ground and Thermal Considerations

As mentioned above, TI recommends using one of the middle layers as a solid ground plane. A ground plane provides shielding for sensitive circuits and traces. A ground plane also provides a quiet reference potential for the control circuitry. Connect the AGND and PGND pins to the ground planes using vias next to the bypass capacitors. PGND pins are connected directly to the source of the low-side MOSFET switch and also connected directly to the grounds of the input and output capacitors. The PGND net contains noise at the switching frequency and can bounce due to load variations. The PGND trace, as well as the VIN and SW traces, must be constrained to one side of the ground planes. The other side of the ground plane contains much less noise and must be used for sensitive routes.

TI recommends providing adequate device heat sinking by using the thermal pad (DAP) of the device as the primary thermal path. Use a minimum  $4 \times 3$  array of 10 mil thermal vias to connect the DAP to the system ground plane heat sink. The vias must be evenly distributed under the DAP. Use as much copper as possible for system ground plane, on the top and bottom layers for the best heat dissipation. Use a four-layer board with the copper thickness for the four layers, starting from the top as: 2 oz / 1 oz / 1 oz / 2 oz. A four-layer board with enough copper thickness and proper layout provides low current conduction impedance, proper shielding, and lower thermal resistance.

### 8.5.2 Layout Example

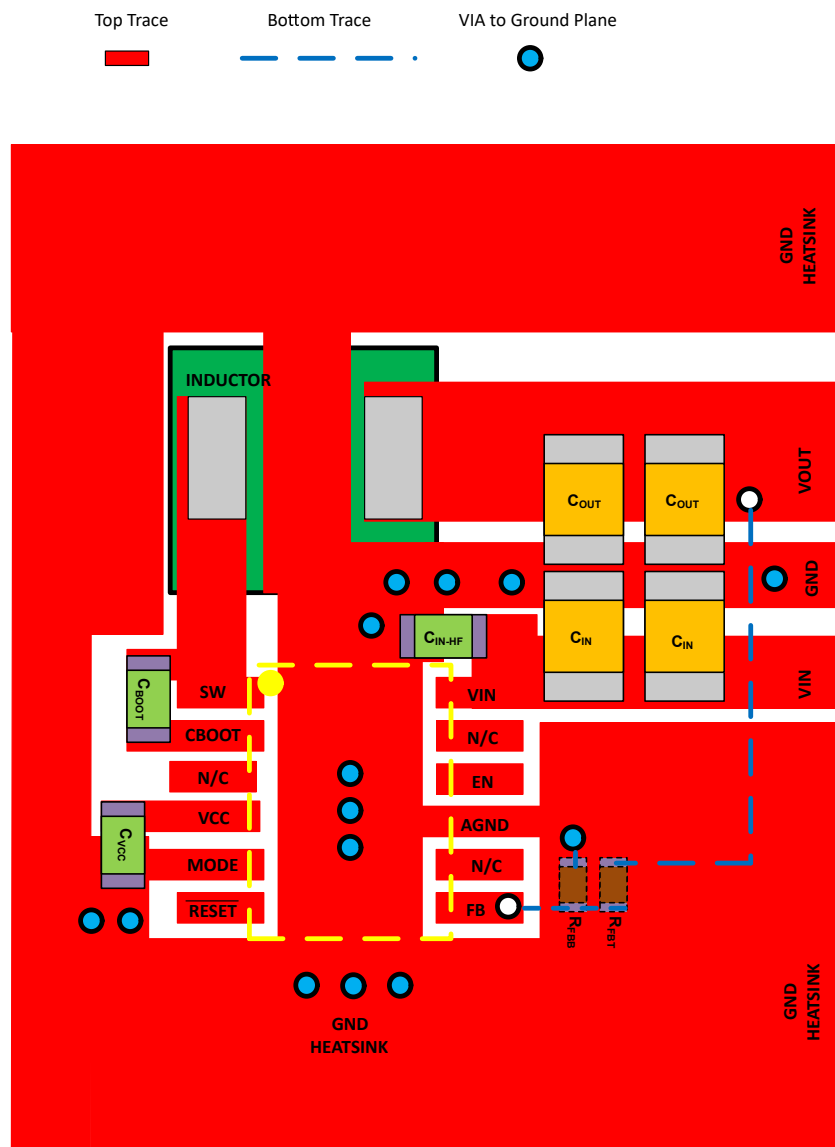


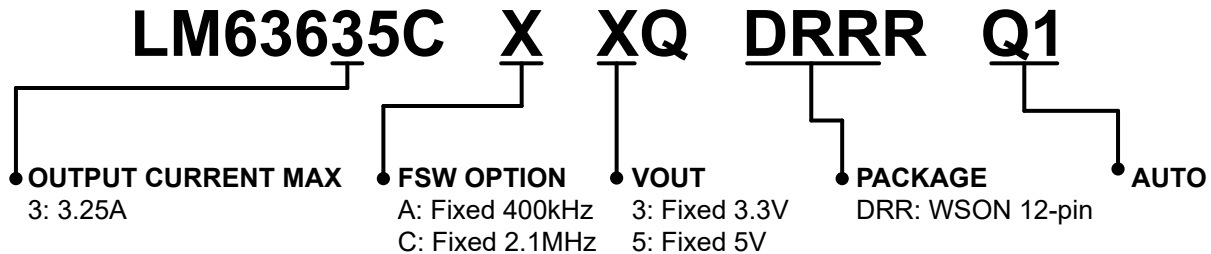
Figure 8-27. Example Layout for WSON Package

## 9 Device and Documentation Support

### 9.1 Device Support

#### 9.1.1 Device Nomenclature

Figure 9-1 shows the device naming nomenclature of the LM63635C-Q1. See [Section 4](#) for the availability of each variant. Contact TI sales representatives or on TI's [E2E™ technical support forum](#) for detail and availability of other options; minimum order quantities apply.



**Figure 9-1. Device Naming Nomenclature**

### 9.2 Documentation Support

#### 9.2.1 Related Documentation

For related documentation see the following:

- Texas Instruments, [AN-2020 Thermal Design By Insight, Not Hindsight](#) application report
- Texas Instruments, [AN-2162 Simple Success with Conducted EMI from DCDC Converters](#) application report
- Texas Instruments, [A Guide to Board Layout for Best Thermal Resistance for Exposed Pad Packages](#) application report
- Texas Instruments, [Semiconductor and IC Package Thermal Metrics](#) application report
- Texas Instruments, [Thermal Design Made Simple with LM43603 and LM43602](#) application report
- Texas Instruments, [Using New Thermal Metrics](#) application report
- Texas Instruments, [Layout Guidelines for Switching Power Supplies](#) application report
- Texas Instruments, [Simple Switcher PCB Layout Guidelines](#) application report
- Texas Instruments, [Constructing Your Power Supply-layout Considerations](#) seminar
- Texas Instruments, [Low Radiated EMI Layout Made Simple with LM4360x and LM4600x](#) application report

### 9.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](#). Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 9.4 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

### 9.5 Trademarks

PowerPAD™ and TI E2E™ are trademarks of Texas Instruments.  
All trademarks are the property of their respective owners.

## 9.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

## 9.7 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

## 10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision * (January 2024) to Revision A (May 2025)	Page
• Changed MODE pin to SYNC/MODE.....	4
• Added negative current limit specification in the <i>Electrical Characteristics</i> table.....	7
• Added OSCILLATOR (SYNC/MODE PIN) section in the <i>Electrical Characteristics</i> table.....	7
• Changed <i>Timing Characteristics</i> table name to <i>Timing Requirements</i> .....	9
• Changed /RESET to $\overline{\text{RESET}}$ in the <i>Timing Requirements</i> table.....	9
• Added $f_{\text{SPREAD}}$ specification in the <i>Switching Characteristics</i> table.....	10
• Added FPWM and frequency synchronization features to the list.....	13
• Changed MODE pin to SYNC/MODE.....	13
• Added connection from the OSCILLATOR block to the CONTROL LOGIC block.....	13
• Added a section describing sync/mode selection.....	13
• Changed frequency spread from $\pm 3\%$ to $\pm 5\%$ .....	14
• Added a paragraph describing device operation when the device is operating in FPWM mode.....	17
• Added <a href="#">Figure 7-8</a> .....	17
• Added <i>Sync/FPWM Operation</i> section.....	18
• Added <i>Switching Frequency vs Input Voltage</i> and load transient curves while the device operates in FPWM mode of operation in the <i>Application Curves</i> section.....	29

## 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

## PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
<a href="#">LM63635CA3QDRRRQ1</a>	Active	Production	WSON (DRR)   12	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	635CA3
LM63635CA3QDRRRQ1.A	Active	Production	WSON (DRR)   12	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	635CA3
<a href="#">LM63635CA5QDRRRQ1</a>	Active	Production	WSON (DRR)   12	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	635CA5
LM63635CA5QDRRRQ1.A	Active	Production	WSON (DRR)   12	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	635CA5
<a href="#">LM63635CC3QDRRRQ1</a>	Active	Production	WSON (DRR)   12	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	635CC3
LM63635CC3QDRRRQ1.A	Active	Production	WSON (DRR)   12	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	635CC3
<a href="#">LM63635CC5QDRRRQ1</a>	Active	Production	WSON (DRR)   12	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	635CC5
LM63635CC5QDRRRQ1.A	Active	Production	WSON (DRR)   12	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	635CC5

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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## TAPE AND REEL INFORMATION



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM63635CA3QDRRRQ1	WSO	DRR	12	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
LM63635CA5QDRRRQ1	WSO	DRR	12	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
LM63635CC3QDRRRQ1	WSO	DRR	12	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
LM63635CC5QDRRRQ1	WSO	DRR	12	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM63635CA3QDRRRQ1	WSN	DRR	12	3000	367.0	367.0	35.0
LM63635CA5QDRRRQ1	WSN	DRR	12	3000	367.0	367.0	35.0
LM63635CC3QDRRRQ1	WSN	DRR	12	3000	367.0	367.0	35.0
LM63635CC5QDRRRQ1	WSN	DRR	12	3000	367.0	367.0	35.0

## GENERIC PACKAGE VIEW

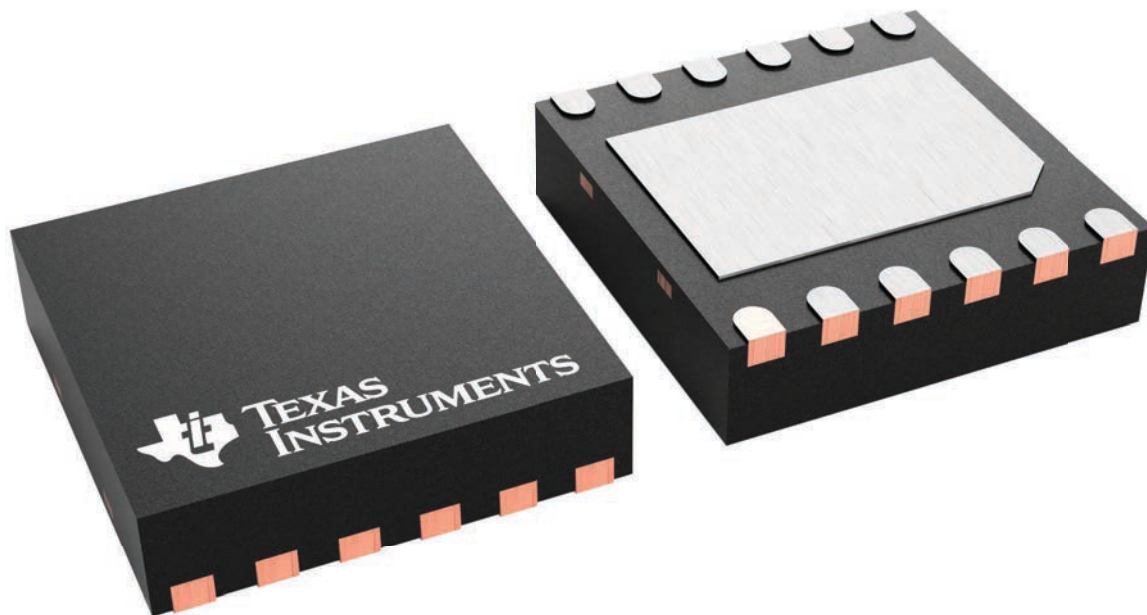
**DRR 12**

**WSON - 0.8 mm max height**

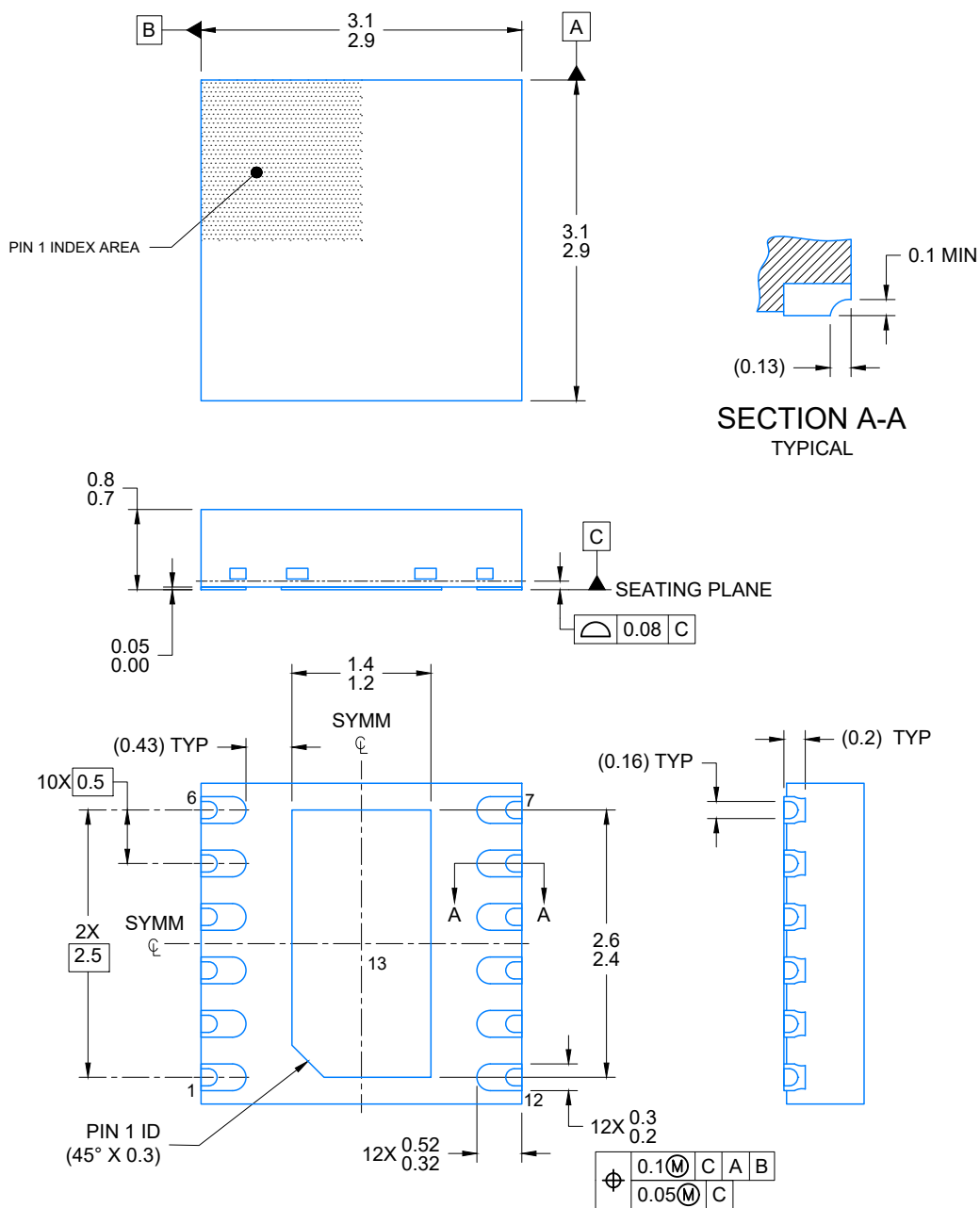
3 x 3, 0.5 mm pitch

PLASTIC SMALL OUTLINE - NO LEAD

This image is a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.



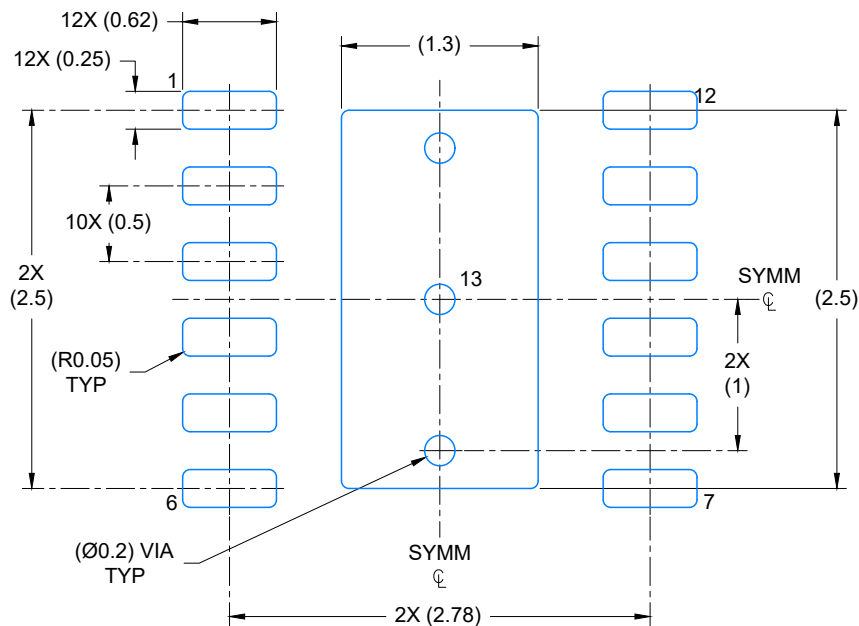
4223490/B



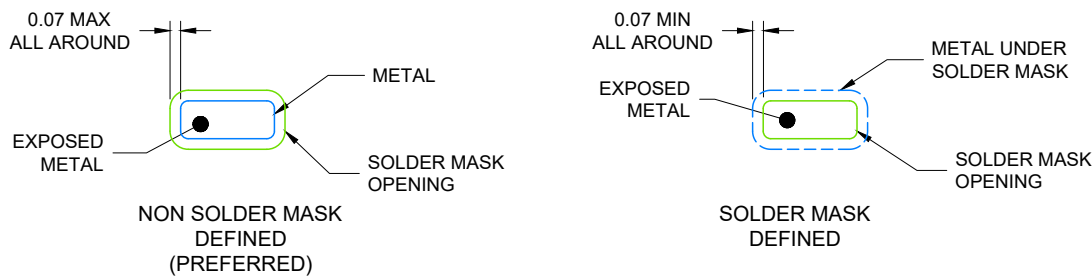
4224874/C 11/2023

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 20X

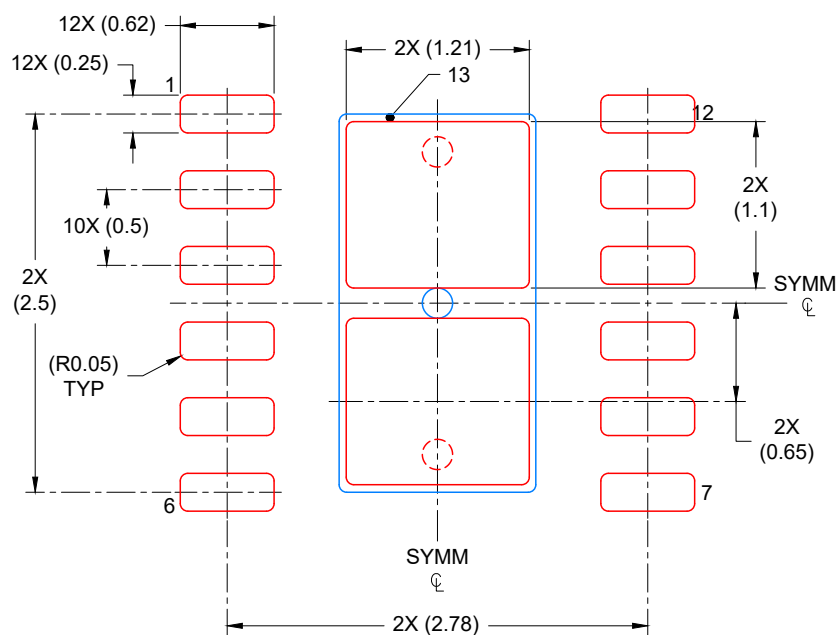


SOLDER MASK DETAILS

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NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/sluea271](http://www.ti.com/lit/sluea271)).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD  
82% PRINTED COVERAGE BY AREA  
SCALE: 20X

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NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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